

I²C Controlled 3A Single Cell USB Charger With Narrow VDC Power Path Management and Adjustable Voltage USB OTG

1 Features

- 90% High Efficiency Switch Mode 3A Charger
- 3.9V-6.2V Single Input USB-compliant Charger with 6.4V Over-Voltage Protection
 - Input voltage and current limit supports USB2.0 and USB 3.0
 - Input Current Limit: 100mA, 150mA, 500mA, 900mA, 1A, 1.5A, 2A, and 3A
- USB OTG with Adjustable output 4.55-5.5V@1A or 1.5A
 - Fast OTG Startup (22ms typ.)
 - 90% 5V Boost Mode Efficiency
 - Accurate +/-15% Hiccup Mode Overcurrent Protection
- Narrow VDC (NVDC) Power Path Management
 - Instant System On with No Battery or Deeply Discharged Battery
 - Ideal Diode Operation in Battery Supplement Mode
- 1.5MHz Switching Frequency for Low Profile 1.2mm Inductor
- I2C port for optimal system performance and status reporting
- Autonomous Battery Charging with or without Host Management
 - Battery Charge Enable
 - Battery Charge Preconditioning
 - Charge Termination and Recharge
- High Accuracy
 - ±0.5% Charge Voltage Regulation
 - ±7% Charge Current Regulation
 - ±7.5% Input Current Regulation
 - ±3% Output Voltage Regulation in USB OTG Boost Mode
- High Integration
 - Power Path Management
 - Synchronous Switching MOSFETs
 - Integrated Current Sensing
 - Bootstrap Diode
 - Internal Loop Compensation

- Safety
 - Battery Temperature Sensing for Charging and Discharging in OTG Mode
 - Battery Charging Safety Timer
 - Thermal Regulation and Thermal Shutdown
 - Input and System Over-Voltage Protection
 - MOSFET Over-Current Protection
- Charge Status Outputs for LED or Host Processor
- Maximum power tracking capability by input voltage regulation
- 20µA Low Battery Leakage Current and Support Shipping Mode
- 4mm x 4mm QFN-24 Package

2 Applications

- Tablet PC
- Smart Phone
- Portable Audio Speaker
- Internet Devices

3 Description

The bq24296M is a highly-integrated switch-mode battery charge management and system power path management device for 1 cell Li-Ion and Li-polymer battery in a wide range of smartphone and tablet applications. Its low impedance power path optimizes switch-mode operation efficiency, reduces battery charging time and extends battery life during discharging phase. The I2C serial interface with charging and system settings makes the device a truly flexible solution.

The device supports a 3.9V-6.2V USB input sources, including standard USB host port and USB charging port with 6.4V over-voltage protection. The device supports USB 2.0 and USB 3.0 power specifications with input current and voltage regulation. To set the default input current limit, the bq24296M takes the result from the detection circuit in the system, such as USB PHY device. The device also supports USB On-the-Go operation by providing fast startup and supplying adjustable voltage 4.55-5.5V (default 5V) on the VBUS with a accurate current limit up to 1.5A.



The power path management regulates the system slightly above battery voltage but does not drop below 3.5V minimum system voltage (programmable). With this feature, the system keeps operating even when the battery is completely depleted or removed. When the input source current or voltage limit is reached, the power path management automatically reduces the charge current to zero and then starts discharges the battery until the system power requirement is met. This supplement mode operation keeps the input source from getting overloaded.

The device initiates and completes a charging cycle when host control is not available. It automatically charges the battery in three phases: pre-conditioning, constant current and constant voltage. In the end, the charger automatically terminates when the charge current is below a preset limit in the constant voltage phase. Later on, when the battery voltage falls below the recharge threshold, the charger will automatically start another charging cycle.

The charge device provides various safety features for battery charging and system operation, including negative thermistor monitoring, charging safety timer and over-voltage/over-current protections. The thermal regulation reduces charge current when the junction temperature exceeds 120° C (programmable).

The STAT output reports the charging status and any fault conditions. The INT immediately notifies host when fault occurs.

The bq24296M is available in a 24-pin, 4x4 mm² thin QFN package.



These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

bq24296M Configuration Table

	bq24296M
I ² C Address	6BH
USB OTG	Yes Adjustable 4.5V-5.5V@1.5A (max)
USB Detection	PSEL
Default Battery Voltage	4.208V
Default Charge Current	2.048A
Default Adapter Current Limit	3A
Default Pre-charge Current / Max Pre-charge Current	128mA / 2.048A
Default Termination Current	256mA
Charging Temperature Profile	Cold/Hot
Status Output	STAT, \overline{PG}
STAT During Fault	Blinking @ 1Hz
Default Safety Timer	12hr
Default VINDPM	4.36V
Default Pre-charge Timer	4hr

Ordering Information

PART NUMBER	PART MARKING	PACKAGE	ORDERING NUMBER	QUANTITY
bq24296M	bq24296M	24-pin 4mmx4mm QFN	bq24296MRGER	3000
			bq24296MRGET	250

4 Application Schematic

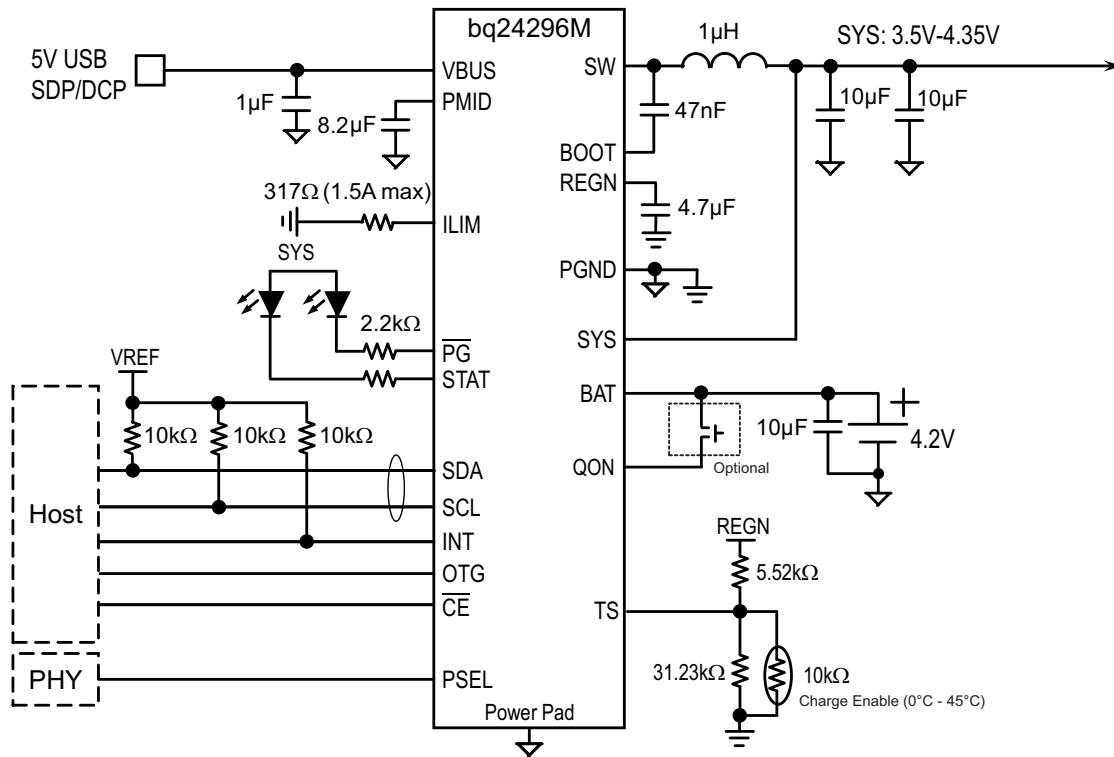
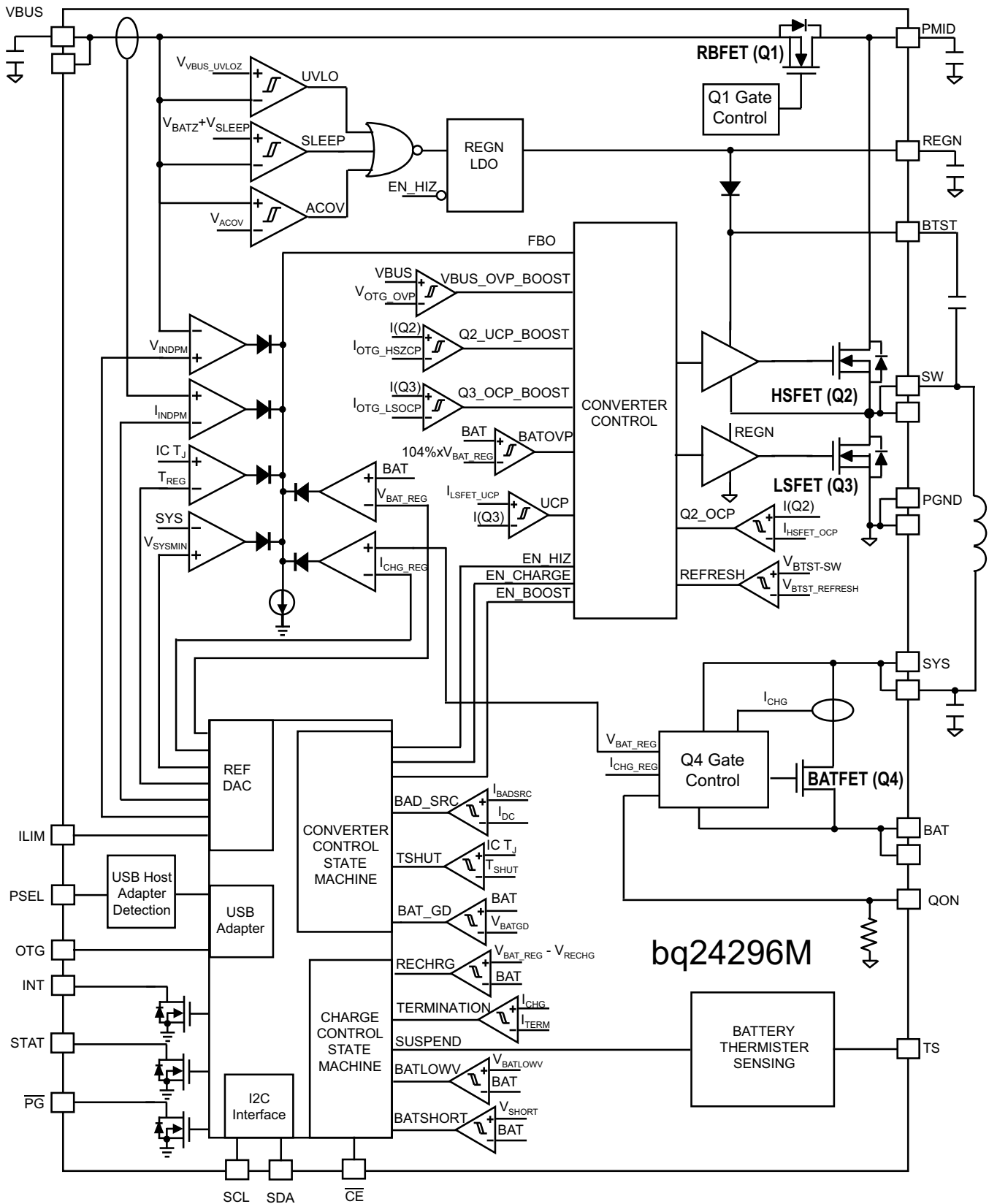
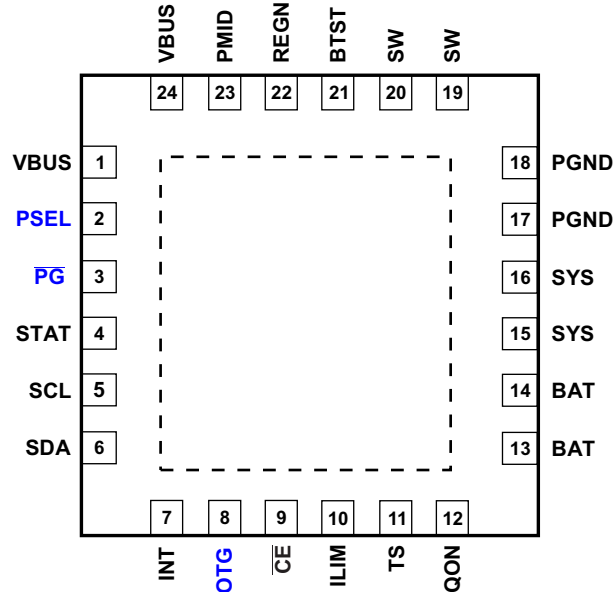


Figure 1. bq24296M with PSEL from PHY, Charging from SDP/DCP, and Optional BATFET Enable Interface

5 Functional Block Diagram



6 Pinout



Pin Functions

PIN		TYPE	DESCRIPTION
NAME	NO.		
VBUS	1,24	P	Charger Input Voltage. The internal n-channel reverse block MOSFET (RBFET) is connected between VBUS and PMID with VBUS on source. Place a 1µF ceramic capacitor from VBUS to PGND and place it as close as possible to IC.
PSEL	2	I	Power source selection input. High indicates a USB host source and Low indicates an adapter source.
$\overline{\text{PG}}$	3	O	Open drain active low power good indicator. Connect to the pull up rail via 10kohm resistor. LOW indicates a good input source if the input voltage is between UVLO and ACOV, above SLEEP mode threshold, and current limit is above 30mA.
STAT	4	O	Open drain charge status output to indicate various charger operation. Connect to the pull up rail via 10kohm. LOW indicates charge in progress. HIGH indicates charge complete or charge disabled. When any fault condition occurs, STAT pin in the charge blinks at 1Hz.
SCL	5	I	I ² C Interface clock. Connect SCL to the logic rail through a 10kΩ resistor.
SDA	6	I/O	I ² C Interface data. Connect SDA to the logic rail through a 10kΩ resistor.
INT	7	O	Open-drain Interrupt Output. Connect the INT to a logic rail via 10kΩ resistor. The INT pin sends active low, 256µs pulse to host to report charger device status and fault.
OTG	8	I Digital	USB current limit selection pin during buck mode, and active high enable pin during boost mode. For bq24296M, when in buck mode with USB host (PSEL=High), when OTG = High, IIN limit = 500mA and when OTG = Low, IIN limit = 100mA. The boost mode is activated when the REG01[5]=1 and OTG pin is High.
$\overline{\text{CE}}$	9	I	Active low Charge Enable pin. Battery charging is enabled when REG01[5:4]=01 and $\overline{\text{CE}}$ pin = Low. $\overline{\text{CE}}$ pin must be pulled high or low.
ILIM	10	I	ILIM pin sets the maximum input current limit by regulating the ILIM voltage at 1V. A resistor is connected from ILIM pin to ground to set the maximum limit as $I_{\text{INMAX}} = (1V/R_{\text{ILIM}}) \times K_{\text{ILIM}}$. The actual input current limit is the lower one set by ILIM and by I ² C REG00[2:0]. The minimum input current programmed on ILIM pin is 500mA.
TS	11	I Analog	Temperature qualification voltage input #1. Connect a negative temperature coefficient thermistor. Program temperature window with a resistor divider from REGN to TS1 to GND. Charge suspends or Boost disable disable when TS pin is out of range. Recommend 103AT-2 thermistor.
QON	12	I	BATFET enable control in shipping mode. A logic low to high transition on this pin with minimum 2ms high level turns on BATFET to exit shipping mode. It has internal 1MΩ (typ.) pull down. For backward compatibility, when BATFET enable control function is not used, the pin can be no connect or tied to TS pin. (Please refer to Shipping Mode for detail description).
BAT	13,14	P	Battery connection point to the positive terminal of the battery pack. The internal BATFET is connected between BAT and SYS. Connect a 10µF closely to the BAT pin.
SYS	15,16	I	System connection point. The internal BATFET is connected between BAT and SYS. When the battery falls below the minimum system voltage, switch-mode converter keeps SYS above the minimum system voltage.
PGND	17,18	P	Power ground connection for high-current power converter node. Internally, PGND is connected to the source of the n-channel LSFET. On PCB layout, connect directly to ground connection of input and output capacitors of the charger. A single point connection is recommended between power PGND and the analog GND near the IC PGND pin.

Pin Functions (continued)

PIN		TYPE	DESCRIPTION
NAME	NO.		
SW	19,20	O	Switching node connecting to output inductor. Internally SW is connected to the source of the n-channel HSFET and the drain of the n-channel LSFET. Connect the 0.047µF bootstrap capacitor from SW to BTST.
BTST	21	P	PWM high side driver positive supply. Internally, the BTST is connected to the anode of the boost-strap diode. Connect the 0.047µF bootstrap capacitor from SW to BTST.
REGN	22	P	PWM low side driver positive supply output. Internally, REGN is connected to the cathode of the boost-strap diode. Connect a 4.7-µF (10V rating) ceramic capacitor from REGN to analog GND. The capacitor should be placed close to the IC. REGN also serves as bias rail of TS pin.
PMID	23	O	Connected to the drain of the reverse blocking MOSFET and the drain of HSFET. Given the total input capacitance, connect a 1-µF capacitor on VBUS to PGND, and the recommended 8.2µF or more on PMID to PGND.
PowerPAD	–	P	Exposed pad beneath the IC for heat dissipation. Always solder PowerPAD™ to the board, and have vias on the PowerPAD plane star-connecting to PGND and ground plane for high-current power converter.

7 Specifications

7.1 Absolute Maximum Ratings⁽¹⁾

		MIN	MAX	UNIT
Voltage range (with respect to GND)	VBUS (converter not switching)	–2	15 ⁽²⁾	V
	PMID (converter not switching)	–0.3	15 ⁽²⁾	V
	STAT, $\overline{\text{PG}}$	–0.3	12	V
	BTST	–0.3	12	V
	SW	–2	7 8 (Peak for 20ns duration)	V
	BAT, SYS (converter not switching)	–0.3	–6	V
	SDA, SCL, INT, OTG, ILIM, REGN, TS, QON $\overline{\text{CE}}$ PSEL	–0.3	–7	V
	BTST TO SW	–0.3	–7	V
	PGND to GND	–0.3	–0.3	V
Output sink current	INT, STAT, $\overline{\text{PG}}$		6	mA
Junction temperature		–40	150	°C
Storage temperature		–65	150	°C

- (1) Stresses beyond those listed under absolute maximum ratings may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under recommended operating conditions is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability. All voltage values are with respect to the network ground terminal unless otherwise noted.
- (2) VBUS is specified up to 16V for a maximum of 24 hours under no load conditions.

7.2 Recommended Operating Conditions

		MIN	MAX	UNIT
V _{IN}	Input voltage	3.9	6.2 ⁽¹⁾	V
I _{IN}	Input current (VBUS)			A
I _{SYS}	Output current (SYS)		3.5	A
V _{BAT}	Battery voltage		4.4	V
I _{BAT}	Fast charging current		3	A
	Discharging current with internal MOSFET		5.5	A
T _A	Operating free-air temperature range	–40	85	°C

- (1) The inherent switching noise voltage spikes should not exceed the absolute maximum rating on either the BTST or SW pins. A tight layout minimizes switching noise.

7.3 Thermal Information

THERMAL METRIC ⁽¹⁾		RGE PACKAGE	UNITS
		24-PIN	
θ_{JA}	Junction-to-ambient thermal resistance	32.2	°C/W
θ_{JCTop}	Junction-to-case (top) thermal resistance	29.8	
θ_{JB}	Junction-to-board thermal resistance	9.1	
Ψ_{JT}	Junction-to-top characterization parameter	0.3	
Ψ_{JB}	Junction-to-board characterization parameter	9.1	
θ_{JCbott}	Junction-to-case (bottom) thermal resistance	2.2	

(1) For more information about traditional and new thermal metrics, see the *IC Package Thermal Metrics* application report, [SPRA953](#).

7.4 Electrical Characteristics

$V_{VBUS_UVLOZ} < V_{VBUS} < V_{ACOV}$ and $V_{VBUS} > V_{BAT} + V_{SLEEP}$, $T_J = -40^{\circ}\text{C}$ to 125°C and $T_J = 25^{\circ}\text{C}$ for typical values unless other noted.

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNITS
QUIESCENT CURRENTS						
I_{BAT}	Battery discharge current (BAT, SW, SYS)	$V_{VBUS} < V_{UVLO}$, $V_{BAT} = 4.2\text{ V}$, leakage between BAT and VBUS		5		μA
		High-Z Mode, or no VBUS, BATFET disabled (REG07[5] = 1), $-40^{\circ}\text{C} - 85^{\circ}\text{C}$		16	20	μA
		High-Z Mode, or no VBUS, BATFET enabled (REG07[5] = 0), $-40^{\circ}\text{C} - 85^{\circ}\text{C}$		32	55	μA
I_{VBUS}	Input supply current (VBUS)	$V_{VBUS} = 5\text{ V}$, High-Z mode, No battery		15	30	μA
		$V_{VBUS} > V_{UVLO}$, $V_{VBUS} > V_{BAT}$, converter not switching		1.5	3	mA
		$V_{VBUS} > V_{UVLO}$, $V_{VBUS} > V_{BAT}$, converter switching, $V_{BAT}=3.2\text{V}$, $I_{SYS}=0\text{A}$		4		mA
		$V_{VBUS} > V_{UVLO}$, $V_{VBUS} > V_{BAT}$, converter switching, charge disable, $V_{BAT}=3.8\text{V}$, $I_{SYS}=100\mu\text{A}$		3.5		mA
I_{BOOST}	Battery Discharge Current in boost mode	$V_{BAT}=4.2\text{V}$, Boost mode, $I_{VBUS} = 0\text{A}$, converter switching		3.5		mA
VBUS/BAT POWER UP						
V_{VBUS_OP}	VBUS operating range		3.9		6.2	V
V_{VBUS_UVLOZ}	VBUS for active I ² C, no battery	V_{VBUS} rising	3.6			V
V_{SLEEP}	Sleep mode falling threshold	V_{VBUS} falling, $V_{VBUS}-V_{BAT}$	35	80	120	mV
V_{SLEEPZ}	Sleep mode rising threshold	V_{VBUS} rising, $V_{VBUS}-V_{BAT}$	170	250	350	mV
V_{ACOV}	VBUS over-voltage rising threshold	V_{VBUS} rising	6.2		6.6	V
V_{ACOV_HYST}	VBUS Over-Voltage Falling Hysteresis	V_{VBUS} falling		250		mV
V_{BAT_UVLOZ}	Battery for active I ² C, no VBUS	V_{BAT} rising	2.3			V
V_{BAT_DPL}	Battery depletion threshold	V_{BAT} falling		2.4	2.6	V
$V_{BAT_DPL_HY}$	Battery depletion rising hysteresis	V_{BAT} rising		200		mV
$V_{VBUSMIN}$	Bad adapter detection threshold	V_{VBUS} falling		3.8		V
I_{BADSRC}	Bad adapter detection current source			30		mA
t_{BADSRC}	Bad source detection duration			30		ms

Electrical Characteristics (continued)

$V_{VBUS_UVLOZ} < V_{VBUS} < V_{ACOV}$ and $V_{VBUS} > V_{BAT} + V_{SLEEP}$, $T_J = -40^{\circ}\text{C}$ to 125°C and $T_J = 25^{\circ}\text{C}$ for typical values unless other noted.

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNITS
POWER PATH MANAGEMENT						
V_{SYS_MAX}	Maximum DC system voltage output	BATFET (Q4) off, V_{BAT} up to 4.35 V			4.43	V
V_{SYS_MIN}	Minimum DC system voltage output	REG01[3:1]=101, $V_{SYSMIN} = 3.5$ V	3.5	3.65		V
$R_{ON(RBFET)}$	Top reverse blocking MOSFET on-resistance between VBUS and PMIID			28	41	mΩ
$R_{ON(HSFET)}$	Internal top switching MOSFET on-resistance between PMID and SW	$T_J = -40^{\circ}\text{C} - 85^{\circ}\text{C}$		39	51	mΩ
		$T_J = -40^{\circ}\text{C} - 125^{\circ}\text{C}$		39	58	
$R_{ON(LSFET)}$	Internal bottom switching MOSFET on-resistance between SW and PGND	$T_J = -40^{\circ}\text{C} - 85^{\circ}\text{C}$		61	82	mΩ
		$T_J = -40^{\circ}\text{C} - 125^{\circ}\text{C}$		61	90	
V_{FWD}	BATFET forward voltage in supplement mode	BAT discharge current 10mA		30		mV
V_{SYS_BAT}	SYS/BAT Comparator	$V_{BAT} < V_{SYSMIN}$, V_{SYS} falling		80		mV
		$V_{BAT} > V_{SYSMIN}$, V_{SYS} falling		180		mV
V_{BATGD}	Battery good comparator rising threshold	V_{BAT} rising		3.55		V
V_{BATGD_HYST}	Battery good comparator falling threshold	V_{BAT} falling		100		mV
BATTERY CHARGER						
$V_{BAT_REG_ACC}$	Charge voltage regulation accuracy	$V_{BAT} = 4.112\text{V}$ and 4.208V	-0.5		0.5	%
$I_{CHG_REG_ACC}$	Fast charge current regulation accuracy	$V_{BAT} = 3.8\text{V}$, $I_{CHG} = 1024\text{mA}$, $T_J = 25^{\circ}\text{C}$	-4		4	%
		$V_{BAT} = 3.8\text{V}$, $I_{CHG} = 1024\text{mA}$, $T_J = -20^{\circ}\text{C} - 125^{\circ}\text{C}$	-7		7	%
		$V_{BAT} = 3.8\text{V}$, $I_{CHG} = 1792\text{mA}$, $T_J = -20^{\circ}\text{C} - 125^{\circ}\text{C}$	-10		10	%
I_{CHG_20pct}	Charge current with 20% option on	$V_{BAT} = 3.1\text{V}$, $I_{CHG} = 104\text{mA}$, REG02=03 and REG02[0]=1		75	175	mA
$V_{BATLOWV}$	Battery LOWV falling threshold	Fast charge to precharge, REG04[1] = 1	2.6	2.8	2.9	V
$V_{BATLOWV_HYST}$	Battery LOWV rising threshold	Precharge to fast charge, REG04[1] = 1 (Typical 200mV hysteresis)	2.8	3.0	3.1	V
I_{PRECHG_ACC}	Precharge current regulation accuracy	$V_{BAT} = 2.6\text{V}$, $I_{CHG} = 256\text{mA}$	-20		20	%
$I_{TYP_TERM_ACC}$	Typical Termination current	$I_{TERM} = 256\text{mA}$, $I_{CHG} = 2048\text{mA}$		265		mA
I_{TERM_ACC}	Termination current accuracy	$I_{TERM} = 256\text{mA}$, $I_{CHG} = 2048\text{mA}$	-22.5		22.5	%
V_{SHORT}	Battery Short Voltage	VBAT falling		2.0		V
V_{SHORT_HYST}	Battery Short Voltage hysteresis	VBAT rising		200		mV
I_{SHORT}	Battery short current	$VBAT < 2.2\text{V}$		100		mA
V_{RECHG}	Recharge threshold below V_{BAT_REG}	VBAT falling, REG04[0] = 0		100		mV
t_{RECHG}	Recharge deglitch time	VBAT falling, REG04[0]=0		20		ms
R_{ON_BATFET}	SYS-BAT MOSFET on-resistance	$T_J = 25^{\circ}\text{C}$		24	28	mΩ
		$T_J = -40^{\circ}\text{C} - 125^{\circ}\text{C}$		24	35	
INPUT VOLTAGE/CURRENT REGULATION						
$V_{INDPM_REG_ACC}$	Input voltage regulation accuracy		-2		2	%
I_{USB_DPM}	USB Input current regulation limit, VBUS = 5V, current pulled from SW	USB100		85	100	mA
		USB150		125	150	mA
		USB500		440	500	mA
		USB900		750	900	mA
I_{ADPT_DPM}	Input current regulation accuracy	IADP=1.5A, REG00[2:0]=101		1.3	1.5	A
I_{IN_START}	Input current limit during system start up	$V_{SYS} < 2.2\text{V}$		100		mA
K_{ILIM}	$I_{IN} = K_{ILIM}/R_{ILIM}$		395	435	475	A x Ω
BAT OVER-VOLTAGE PROTECTION						
V_{BATOVP}	Battery over-voltage threshold	V_{BAT} rising, as percentage of V_{BAT_REG}		104		%
V_{BATOVP_HYST}	Battery over-voltage hysteresis	V_{BAT} falling, as percentage of V_{BAT_REG}		2		%
t_{BATOVP}	Battery over-voltage deglitch time to disable charge			1		μs
THERMAL REGULATION AND THERMAL SHUTDOWN						
$T_{Junction_REG}$	Junction temperature regulation accuracy	REG06[1:0] = 11		120		°C

Electrical Characteristics (continued)

$V_{VBUS_UVLOZ} < V_{VBUS} < V_{ACOV}$ and $V_{VBUS} > V_{BAT} + V_{SLEEP}$, $T_J = -40^{\circ}\text{C}$ to 125°C and $T_J = 25^{\circ}\text{C}$ for typical values unless other noted.

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNITS
T_{SHUT}	Thermal shutdown rising temperature	Temperature increasing		160		$^{\circ}\text{C}$
T_{SHUT_HYS}	Thermal shutdown hysteresis			30		$^{\circ}\text{C}$
	Thermal shutdown rising deglitch	Temperature increasing delay		1		ms
	Thermal shutdown falling deglitch	Temperature decreasing delay		1		ms
COLD/HOT THERMISTER COMPARATOR						
V_{LTF}	Cold temperature threshold, TS pin voltage rising threshold	Charger suspends charge. As Percentage to V_{REGN}	73	73.5%	74	%
V_{LTF_HYS}	Cold temperature hysteresis, TS pin voltage falling	As Percentage to V_{REGN}		0.4		%
V_{HTF}	Hot temperature TS pin voltage falling threshold	As Percentage to V_{REGN}	46.6	47.2	48.8	%
V_{TCO}	Cut-off temperature TS pin voltage falling threshold	As Percentage to V_{REGN}	44.2	44.7	45.2	%
	Deglitch time for temperature out of range detection	$V_{TS} > V_{LTF}$, or $V_{TS} < V_{TCO}$, or $V_{TS} < V_{HTF}$		10		ms
VBCOLD0	Cold Temperature Threshold, TS pin Voltage Rising Threshold	As Percentage to V_{REGN} REG02[1]=0 (Approx. -10°C w/ 103AT)	75.5	76	76.5	%
VBCOLD0_HYS		As Percentage to V_{REGN} REG02[1]=0 (Approx. 1°C w/ 103AT)		1		%
VBCOLD1	Cold Temperature Threshold 1, TS pin Voltage Rising Threshold	As Percentage to V_{REGN} REG02[1]=1 (Approx. -20°C w/ 103AT)	78.5	79	79.5	%
VBCOLD1_HYS		As Percentage to V_{REGN} REG02[1]=1 (Approx. 1°C w/ 103AT)		1		%
VBHOT0	Hot Temperature Threshold, TS pin Voltage falling Threshold	As Percentage to V_{REGN} REG06[3:2]= 01 (Approx. 55°C w/ 103AT)	35.5	36	36.5	%
VBHOT0_HYS		As Percentage to V_{REGN} REG06[3:2]= 01 (Approx. 3°C w/ 103AT)		3		%
VBHOT1	Hot Temperature Threshold 1, TS pin Voltage falling Threshold	As Percentage to V_{REGN} REG06[3:2]= 00 (Approx. 60°C w/ 103AT)	32.5	33	33.5	%
VBHOT1_HYS		As Percentage to V_{REGN} REG06[3:2]= 00 (Approx. 3°C w/ 103AT)		3		%
VBHOT2	Hot Temperature Threshold 2, TS pin Voltage falling Threshold	As Percentage to V_{REGN} REG06[3:2]= 10 (Approx. 65°C w/ 103AT)	29.5	30	30.5	%
VBHOT2_HYS		As Percentage to V_{REGN} REG06[3:2]= 10 (Approx. 3°C w/ 103AT)		3		%
CHARGE OVER-CURRENT COMPARATOR						
I_{HSFET_OCP}	HSFET cycle by cycle over-current threshold		5.3	7.5		A
V_{LSFET_UCP}	LSFET charge under-current falling threshold	From sync mode to non-sync mode		100		mA
F_{SW}	PWM Switching frequency, and digital clock		1300	1500	1700	kHz
D_{MAX}	Maximum PWM duty cycle			97		%
$V_{BTST_REFRESH}$	Bootstrap refresh comparator threshold	$V_{BTST} - V_{SW}$ when LSFET refresh pulse is requested, $V_{BUS} = 5V$		3.6		V
BOOST MODE OPERATION						
$V_{OTG_REG_ACC}$	OTG output voltage	$I(V_{BUS}) = 0$, REG06[7:4]=0111 (4.998V)		5		V
$V_{OTG_REG_ACC}$	OTG output voltage accuracy	$I(V_{BUS}) = 0$, REG06[7:4]=0111 (4.998V)	-3		3	%
V_{OTG_BAT}	Battery voltage exiting OTG mode	BAT falling, REG04[1]=1	2.9			V
I_{OTG}	OTG mode output current	REG01[0] = 0	1			A
		REG01[0] = 1	1.5			A
V_{OTG_OVP}	OTG over-voltage threshold	Rising Threshold	5.8	6		V
$V_{OTG_OVP_HYS}$	OTG over-voltage threshold hysteresis	Falling Threshold		300		mV
I_{OTG_LSOCP}	LSFET cycle by cycle current limit		5			A
I_{OTG_HSZCP}	HSFET under current falling threshold			100		mA
I_{RBFET_OCP}	RBFET over-current threshold	REG01[0] = 0	1.00	1.15	1.30	A
		REG01[0] = 1	1.50	1.70	1.90	

Electrical Characteristics (continued)

$V_{VBUS_UVLOZ} < V_{VBUS} < V_{ACOV}$ and $V_{VBUS} > V_{BAT} + V_{SLEEP}$, $T_J = -40^{\circ}\text{C}$ to 125°C and $T_J = 25^{\circ}\text{C}$ for typical values unless other noted.

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNITS
$t_{OTG_OCP_OFF}$	OTG mode over-current protection off cycle time			32		ms
$t_{OTG_OCP_ON}$	OTG mode over-current protection on cycle time			260		μs
REGN LDO						
V_{REGN}	REGN LDO output voltage	$V_{VBUS} = 6\text{V}, I_{REGN} = 40\text{mA}$	4.8	5	5.5	V
		$V_{VBUS} = 5\text{V}, I_{REGN} = 20\text{mA}$	4.7	4.8		V
I_{REGN}	REGN LDO current limit	$V_{VBUS} = 5\text{V}, V_{REGN} = 3.8\text{V}$	50			mA
QON Timing						
t_{QON}	QON pin high time to turn on BATFET		2			ms
LOGIC I/O PIN CHARACTERISTICS (OTG, $\overline{\text{CE}}$, STAT, QON, PSEL, $\overline{\text{PG}}$)						
V_{ILO}	Input low threshold				0.4	V
V_{IH}	Input high threshold		1.3			V
V_{OUT_LO}	Output low saturation voltage	Sink current = 5 mA			0.4	V
I_{BIAS}	High level leakage current (OTG, $\overline{\text{CE}}$, STAT, PSEL, $\overline{\text{PG}}$)	Pull up rail 1.8V			1	μA
I_{BIAS}	High level leakage current (QON)	Pull up rail 3.6V			8	μA
I²C INTERFACE (SDA, SCL, INT)						
V_{IH}	Input high threshold level	VPULL-UP = 1.8V, SDA and SCL	1.3			V
V_{IL}	Input low threshold level	VPULL-UP = 1.8V, SDA and SCL			0.4	V
V_{OL}	Output low threshold level	Sink current = 5mA			0.4	V
I_{BIAS}	High-level leakage current	VPULL-UP = 1.8V, SDA and SCL			1	μA
f_{SCL}	SCL clock frequency				400	kHz
DIGITAL CLOCK AND WATCHDOG TIMER						
f_{HIZ}	Digital crude clock	REGN LDO disabled	15	35	50	kHz
f_{DIG}	Digital clock	REGN LDO enabled	1300	1500	1700	kHz
		REGN LDO disabled	112	160		sec
t_{WDT}	REG05[5:4]=11	REGN LDO disabled	136	160		sec
		REGN LDO enabled				

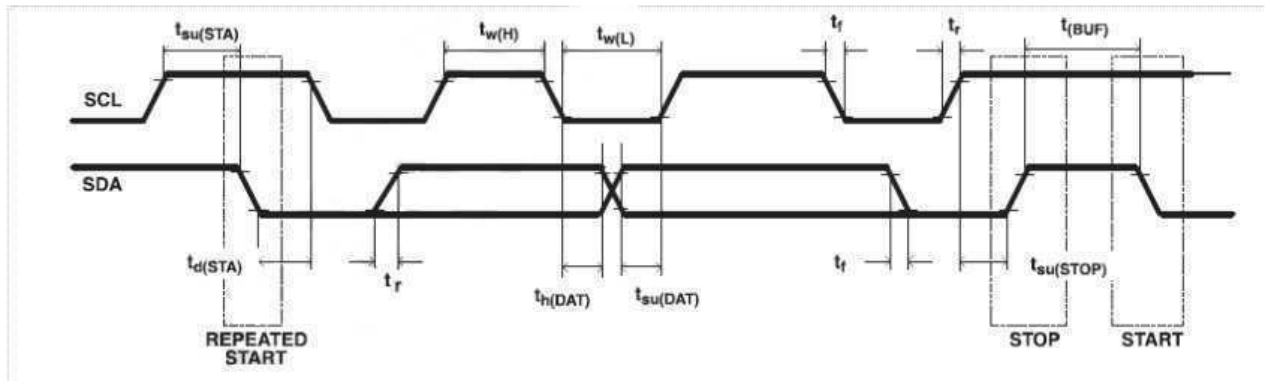


Figure 2. I²C-Compatible Interface Timing Diagram

8 Typical Characteristics

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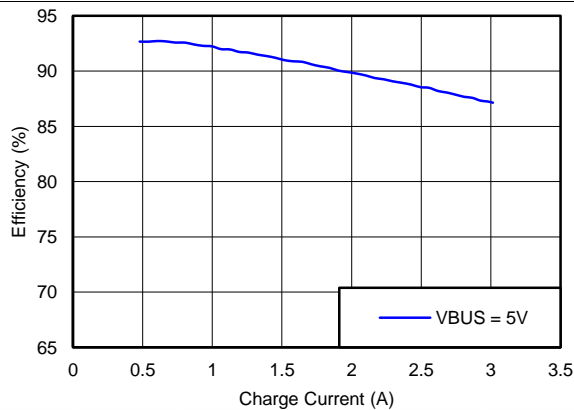


Figure 3. Charge Efficiency vs Charge Current

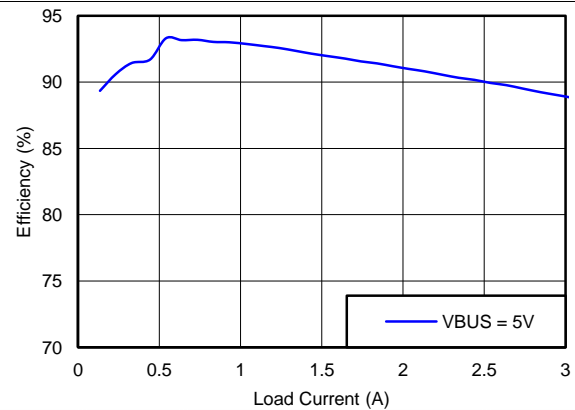


Figure 4. System Efficiency vs System Load Current

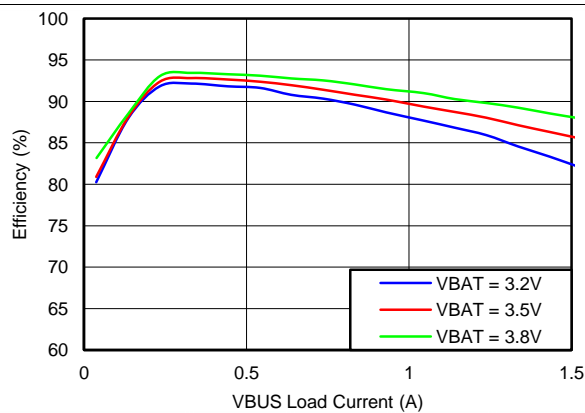


Figure 5. Boost Mode Efficiency vs VBUS Load Current

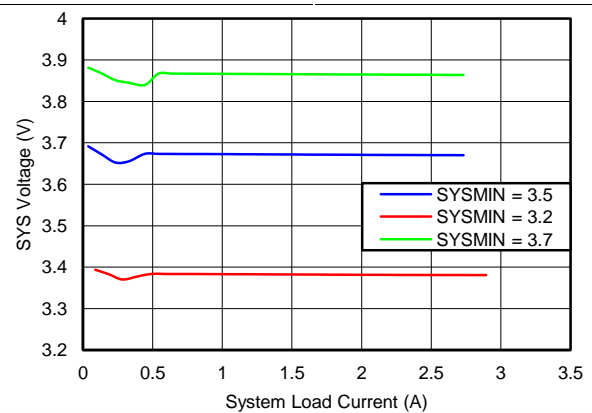


Figure 6. SYS Voltage Regulation vs System Load Current

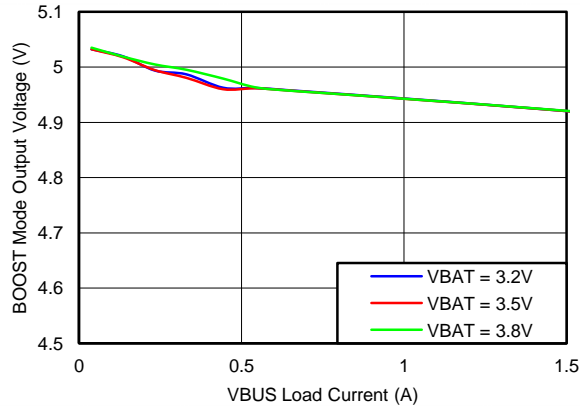


Figure 7. Boost Mode VBUS Voltage Regulation (Typical Output = 4.998V ; REG06[7:4]=0111) vs VBUS Load Current

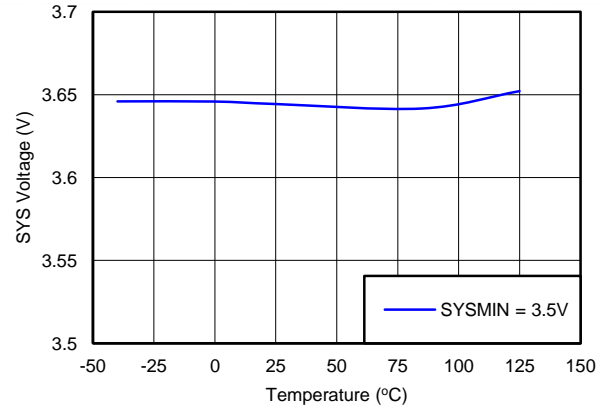


Figure 8. SYS Voltage vs Temperature

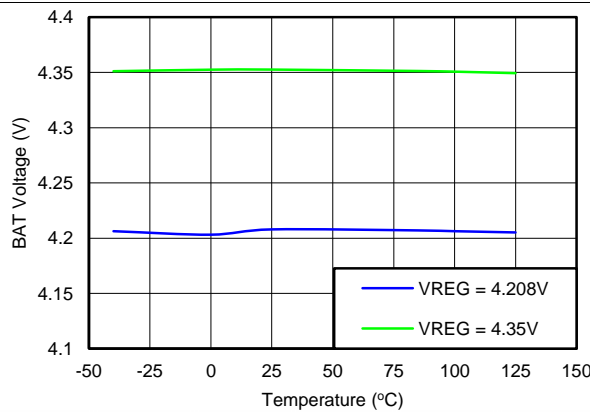


Figure 9. BAT Voltage vs Temperature

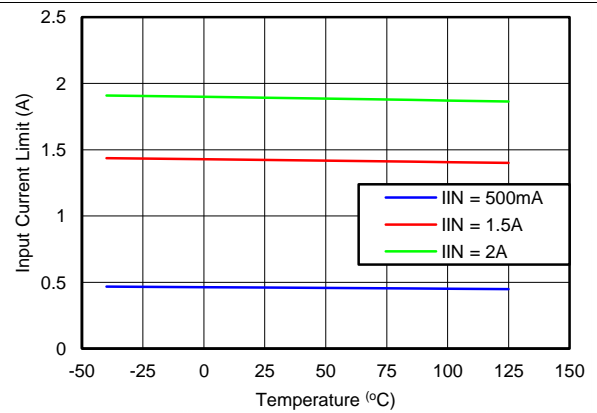


Figure 10. Input Current Limit vs Temperature

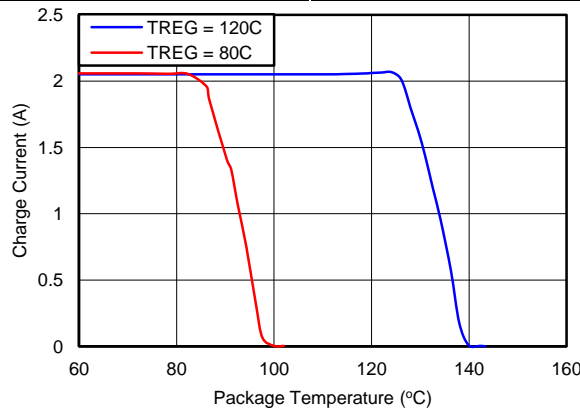


Figure 11. Charge Current vs Package Temperature

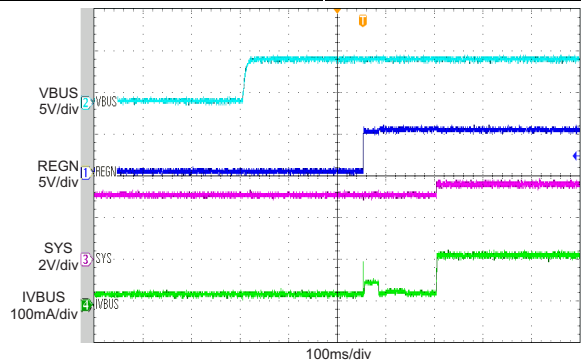


Figure 12. Power Up with Charge Enabled (VBAT = 3.2V)

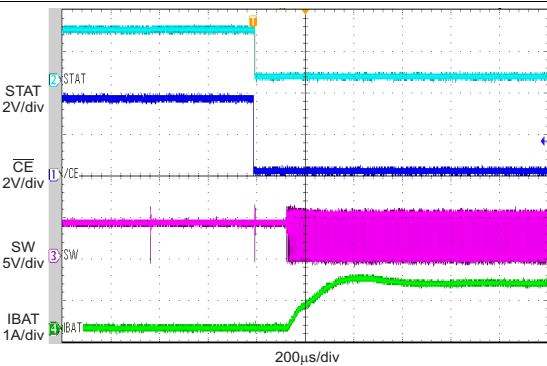


Figure 13. Charge Enable (VBUS = 5V)

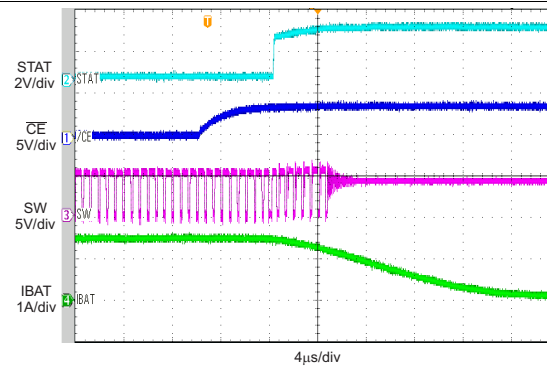


Figure 14. Charge Disable

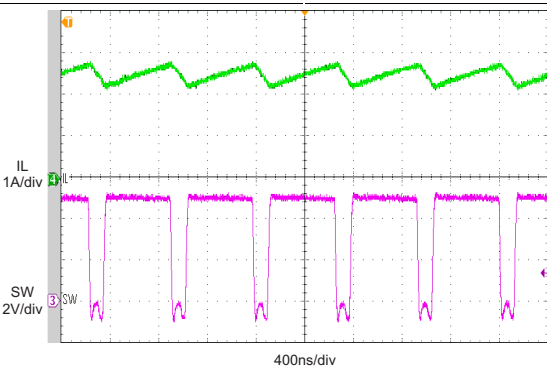


Figure 15. PWM Switching in Buck Mode (VBUS = 5V, No Battery, ISYS = 40mA, Charge Disable)

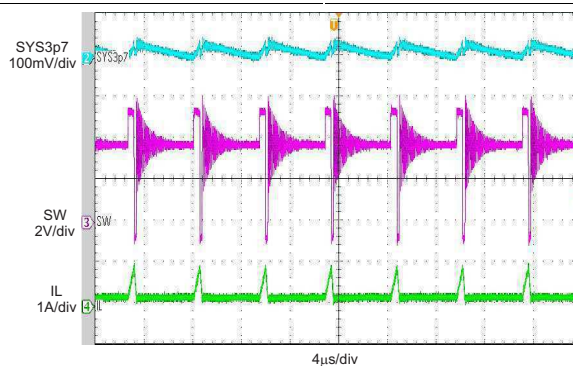


Figure 16. PFM Switching in Buck Mode (VBUS = 5V, VBAT = 3.6V, ICHG = 2.5A)

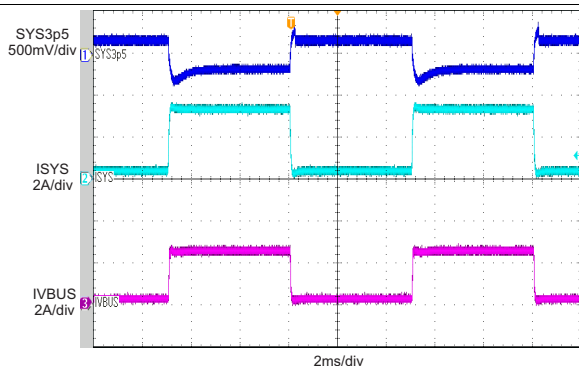


Figure 17. Input Current DPM Response Without Battery (VBUS = 5V, IIN = , No Battery, Charge Disable)

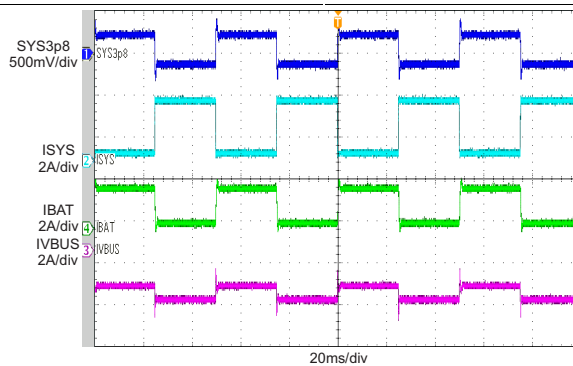


Figure 18. Load Transient During Supplement Mode (VBUS = 5V, IIN = , VBAT = 3.8V)

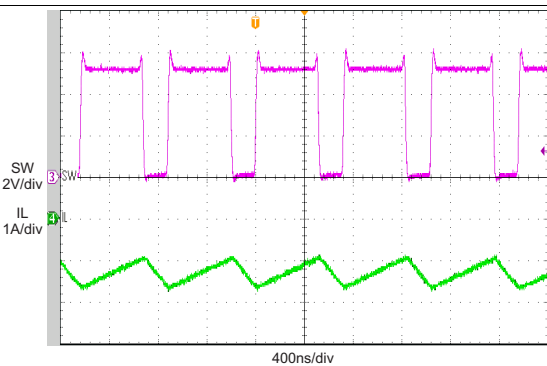


Figure 19. Boost Mode Switching (VBAT = 3.8V, ILOAD = 1A)

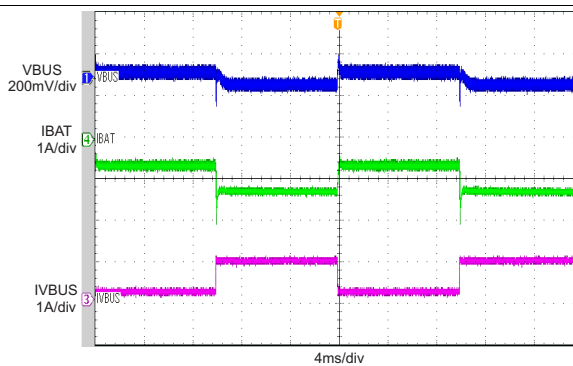


Figure 20. Boost Mode Load Transient (VBAT = 3.8V)

9 I²C Registers

Address: 6BH. REG00-07 support Read and Write. REG08-0A are read only.

Input Source Control Register REG00 (default 00110xxx, or 3x)

BIT		DESCRIPTION	
Bit 7	EN_HIZ	0 – Disable, 1 – Enable	Default: Disable (0)
Input Voltage Limit			
Bit 6	VINDPM[3]	640mV	Offset 3.88V, Range: 3.88V-5.08V Default: 4.36V (0110)
Bit 5	VINDPM[2]	320mV	
Bit 4	VINDPM[1]	160mV	
Bit 3	VINDPM[0]	80mV	
Input Current Limit (Actual input current limit is the lower of I ² C and ILIM)			
Bit 2	IINLIM[2]	000 – 100mA, 001 – 150mA, 010 – 500mA, 011 – 900mA, 100 – 1A, 101 – 1.5A, 110 – 2A, 111 – 3A	PSEL=Lo : 3A (111) PSEL=Hi : 100mA (000) (OTG pin =Lo) or 500mA (OTG pin=Hi)
Bit 1	IINLIM[1]		
Bit 0	IINLIM[0]		

Power-On Configuration Register REG01 (default 00011011, or 1B)

BIT		DESCRIPTION	NOTE
Bit 7	Register Reset	0 – Keep current register setting, 1 – Reset to default	Default: Keep current register setting (0) Note: Register Reset bit does not reset device to default mode
Bit 6	I ² C Watchdog Timer Reset	0 – Normal ; 1 – Reset	Default: Normal (0) Note: Consecutive I2C watchdog timer reset requires minimum 20uS delay
Charger Configuration			
Bit 5	OTG_CONFIG	0 – OTG Disable; 1 – OTG Enable	Default: OTG disable (0) Note: OTG_CONFIG would over-ride Charge Enable Function in CHG_CONFIG
Bit 4	CHG_CONFIG	0- Charge Disable; 1- Charge Enable	Default: Charge Battery (1)
Minimum System Voltage Limit			
Bit 3	SYS_MIN[2]	0.4V	Offset: 3.0V, Range 3.0V-3.7V Default: 3.5V (101)
Bit 2	SYS_MIN[1]	0.2V	
Bit 1	SYS_MIN[0]	0.1V	
Bit 0	BOOST_LIM	0 – 1A, 1 – 1.5A	Default: 1.5A (1)

Charge Current Control Register REG02 (default 01100000, or 60)

BIT		DESCRIPTION	NOTE
Fast Charge Current Limit			
Bit 7	ICHG[5]	2048mA	Offset: 512mA Range: 512-3008mA (000000 - 100111) Default: 2048mA (011000) Note: ICHG higher than 3008mA is not supported
Bit 6	ICHG[4]	1024mA	
Bit 5	ICHG[3]	512mA	
Bit 4	ICHG[2]	256mA	
Bit 3	ICHG[1]	128mA	
Bit 2	ICHG[0]	64mA	
Bit 1	BCOLD	Set Boost Mode temperature monitor threshold voltage to disable boost mode 0 – V _{bcold0} (Typ. 76% of REGN or -10°C w/ 103AT thermistor) 1 – V _{bcold1} (Typ. 79% of REGN or -20°C w/ 103AT thermistor)	Default: V _{bcold0} (0)
Bit 0	FORCE_20PCT	0 – ICHG as Fast Charge Current (REG02[7:2]) and IPRECH as Pre-Charge Current (REG03[7:4]) programmed 1 – ICHG as 20% Fast Charge Current (REG02[7:2]) and IPRECH as 50% Pre-Charge Current (REG03[7:4]) programmed	Default: ICHG as Fast Charge Current (REG02[7:2]) and IPRECH as Pre-Charge Current (REG03[7:4]) programmed (0)

Pre-Charge/Termination Current Control Register REG 03 (default 00010001, or 0x11)

BIT		DESCRIPTION	NOTE
Pre-Charge Current Limit			
Bit 7	IPRECHG[3]	0000: 128mA; 0001: 128mA; 0010: 256mA;	Offset: 128mA, Range: 128mA – 2048mA Default: 128mA (0001)
Bit 6	IPRECHG[2]	0011: 384mA	
Bit 5	IPRECHG[1]	0100: 512mA; 0101: 768mA; 0110: 896mA;	
Bit 4	IPRECHG[0]	0111: 1024mA 1000: 1152mA; 1001: 1280mA; 1010: 1408mA; 1011: 1536mA 1100: 1664mA; 1101: 1792mA; 1110: 1920mA; 1111: 2048mA	
Bit 3	Reserved	0 - Reserved	
Termination Current Limit			
Bit 2	ITERM[2]	512mA	Offset: 128mA Range: 128mA – 1024mA Default: 256mA (001)
Bit 1	ITERM[1]	256mA	
Bit 0	ITERM[0]	128mA	

Charge Voltage Control Register REG04 (default 10110010, or 0xB2)

BIT		DESCRIPTION	NOTE
Charge Voltage Limit			
Bit 7	VREG[5]	512mV	Offset: 3.504V Range: 3.504V – 4.400V Default: 4.208V
Bit 6	VREG[4]	256mV	
Bit 5	VREG[3]	128mV	
Bit 4	VREG[2]	64mV	
Bit 3	VREG[1]	32mV	
Bit 2	VREG[0]	16mV	
Bit 1	BATLOWV	0 – 2.8V, 1 – 3.0V	Default: 3.0V (1) (pre-charge to fast charge)
Battery Recharge Threshold (below battery regulation voltage)			
Bit 0	VRECHG	0 – 100mV, 1 – 300mV	Default: 100mV (0)

Charge Termination/Timer Control Register REG05 (default 10011010, or 0x9A)

BIT		DESCRIPTION	NOTE
Charging Termination Enable			
Bit 7	EN_TERM	0 – Disable, 1 – Enable	Default: Enable termination (1)
Bit 6	Reserved	0 - Reserved	
I2C Watchdog Timer Setting			
Bit 5	WATCHDOG[1]	00 – Disable timer, 01 – 40s, 10 – 80s, 11 – 160s	Default: 40s (01)
Bit 4	WATCHDOG[0]		
Charging Safety Timer Enable			
Bit 3	EN_TIMER	0 – Disable, 1 – Enable	Default: Enable (1)
Fast Charge Timer Setting			
Bit 2	CHG_TIMER[1]	00 – 5 hrs, 01 – 8 hrs, 10 – 12 hrs, 11 – 20 hrs	Default: 12 hrs (10) (See Charging Safety Timer for details)
Bit 1	CHG_TIMER[0]		
Bit 0	Reserved	0 - Reserved	

Boost Voltage/Thermal Regulation Control Register REG06 (default 01110011, or 0x73)

BIT		DESCRIPTION	NOTE
Bit 7	BOOSTV[3]	512mV	Offset: 4.55V Range: 4.55V – 5.51V Default: 4.998V(0111)
Bit 6	BOOSTV[2]	256mV	
Bit 5	BOOSTV[1]	128mV	
Bit 4	BOOSTV[0]	64mV	
Bit 3	BHOT[1]	Set Boost Mode temperature monitor threshold voltage to disable boost mode Voltage to disable boost mode 00 – V_{bhot1} (33% of REGN or 55°C w/ 103AT thermistor) 01 – V_{bhot0} (36% of REGN or 60°C w/ 103AT thermistor) 10 – V_{bhot2} (30% of REGN or 65°C w/ 103AT thermistor) 11 – Disable boost mode thermal protection.	Default: V_{bhot1} (00) Note: For BHOT[1:0]=11, boost mode operates without temperature monitor and the NTC_FAULT is generated based on V_{bhot1} threshold
Bit 2	BHOT[0]		
Thermal Regulation Threshold			
Bit 1	TREG[1]	00 – 60°C, 01 – 80°C, 10 – 100°C, 11 – 120°C	Default: 120°C (11)
Bit 0	TREG[0]		

Misc Operation Control Register REG07 (default 01001011, or 4B)

BIT		DESCRIPTION	NOTE
Force DPDM detection			
Bit 7	DPDM_EN	0 – Not in Force detection; 1 – Force detection when VBUS power is presence	Default: Not in Force detection (0), Back to 0 after detection complete
Safety Timer Setting during Input DPM and Thermal Regulation			
Bit 6	TMR2X_EN	0 – Safety timer not slowed by 2X during input DPM or thermal regulation, 1 – Safety timer slowed by 2X during input DPM or thermal regulation	Default: Safety timer slowed by 2X (1)
Force BATFET Off			
Bit 5	BATFET_Disable	0 – Allow BATFET (Q4) turn on, 1 – Turn off BATFET (Q4)	Default: Allow BATFET (Q4) turn on(0)
Bit 4	Reserved	0 - Reserved	
Bit 3	Reserved	1 - Reserved	
Bit 2	Reserved	0 - Reserved	
Bit 1	INT_MASK[1]	0 – No INT during CHRG_FAULT, 1 – INT on CHRG_FAULT	Default: INT on CHRG_FAULT (1)
Bit 0	INT_MASK[0]	0 – No INT during BAT_FAULT, 1 – INT on BAT_FAULT	Default: INT on BAT_FAULT (1)

System Status Register REG08

BIT		DESCRIPTION
Bit 7	VBUS_STAT[1]	00 – Unknown (no input, or DPDM detection incomplete), 01 – USB host, 10 – Adapter port, 11 – OTG
Bit 6	VBUS_STAT[0]	
Bit 5	CHRG_STAT[1]	00 – Not Charging, 01 – Pre-charge ($<V_{BATLOWV}$), 10 – Fast Charging, 11 – Charge Termination Done
Bit 4	CHRG_STAT[0]	
Bit 3	DPM_STAT	0 – Not DPM, 1 – VINDPM or IINDPM
Bit 2	PG_STAT	0 – Not Power Good, 1 – Power Good
Bit 1	THERM_STAT	0 – Normal, 1 – In Thermal Regulation
Bit 0	VSYS_STAT	0 – Not in VSYSMIN regulation ($BAT > VSYSMIN$), 1 – In VSYSMIN regulation ($BAT < VSYSMIN$)

New Fault Register REG09 ⁽¹⁾⁽²⁾⁽³⁾

BIT		DESCRIPTION
Bit 7	WATCHDOG_FAULT	0 – Normal, 1- Watchdog timer expiration
Bit 6	OTG_FAULT	0 – Normal, 1 – VBUS overloaded in OTG, or VBUS OVP, or battery is too low (any conditions that we cannot start boost function)
Bit 5	CHRG_FAULT[1]	00 – Normal, 01 – Input fault (OVP or bad source), 10 - Thermal shutdown, 11 – Charge Timer Expiration
Bit 4	CHRG_FAULT[0]	
Bit 3	BAT_FAULT	0 – Normal, 1 – System OVP
Bit 2	Reserved	Reserved – 0
Bit 1	NTC_FAULT[1]	0-Normal 1–Cold Note: Cold temperature threshold is different based on device operates in buck or boost mode
Bit 0	NTC_FAULT[0]	0-Normal 1–Hot Note: Hot temperature threshold is different based on device operates in buck or boost mode

(1) REG09 only supports single byte i2c read.

(2) All register bits in REG09 are latched fault. First time read of REG09 will clear the previous fault and second read will update fault register to any fault that still presents.

(3) When adapter is unplugged, input fault (bad source) in CHRG_FAULT bits[5:4] will be set to 01 once.

Vender / Part / Revision Status Register REG0A

BIT		DESCRIPTION
Bit 7	PN[2]	001 (bq24296M)
Bit 6	PN[1]	
Bit 5	PN[0]	
Bit 4	Reserved	0 – Reserved
Bit 3	Reserved	0 – Reserved
Bit 2	Rev[2]	000
Bit 1	Rev[1]	
Bit 0	Rev[0]	

10 Detailed Description

The bq24296M is an I²C controlled power path management device and a single cell Li-Ion battery charger. It integrates the input reverse-blocking FET (RBFET, Q1), high-side switching FET (HSFET, Q2), low-side switching FET (LSFET, Q3), and battery FET (BATFET, Q4) between system and battery. The device also integrates the bootstrap diode for the high-side gate drive.

10.1 Device Power Up

10.1.1 Power-On-Reset (POR)

The internal bias circuits are powered from the higher voltage of VBUS and BAT. When VBUS or VBAT rises above UVLOZ, the sleep comparator, battery depletion comparator and BATFET driver are active. I²C interface is ready for communication and all the registers are reset to default value. The host can access all the registers after POR.

10.1.2 Power Up from Battery without DC Source

If only battery is present and the voltage is above depletion threshold (V_{BAT_DEPL}), the BATFET turns on and connects battery to system. The REGN LDO stays off to minimize the quiescent current. The low R_{DSON} in BATFET and the low quiescent current on BAT minimize the conduction loss and maximize the battery run time.

10.1.2.1 BATFET Turn Off

The BATFET can be forced off by the host through I²C REG07[5]. This bit allows the user to independently turn off the BATFET when the battery condition becomes abnormal during charging. When BATFET is off, there is no path to charge or discharge the battery. When battery is not attached, the BATFET should be turned off by setting REG07[5] to 1 to disable charging and supplement mode.

10.1.2.2 Shipping Mode

To extend battery life and minimize power when system is powered off during system idle, shipping, or storage, the device can turn off BATFET so that the system voltage is zero to minimize the leakage. The BATFET can be turned off by setting REG07[5] (BATFET_DISABLE) bit.

In order to keep BATFET off during shipping mode, the host has to disable the watchdog timer (REG05[5:4]=00) and disable BATFET (REG07[5]=1) at the same time. Once the BATFET is disabled, one of the following events can turn on BATFET and clear REG07[5] (BATFET_DISABLE) bit.

1. Plug in adapter
2. Write REG07[5]=0
3. watchdog timer expiration
4. Register reset (REG01[7]=1)
5. A logic low to high transition on QON pin (refer to [Figure 21](#) for detail timing)

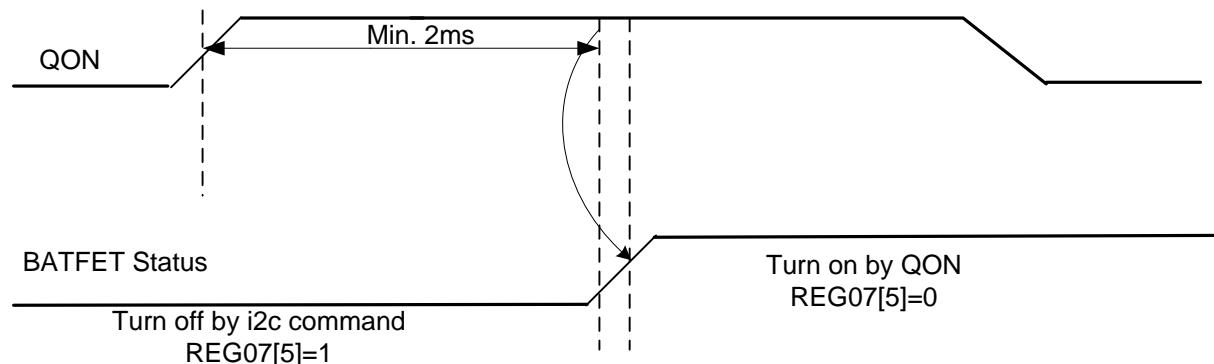


Figure 21. QON Timing

Device Power Up (continued)

10.1.3 Power Up from DC Source

When the DC source plugs in, the charger device checks the input source voltage to turn on REGN LDO and all the bias circuits. It also checks the input current limit before starts the buck converter.

10.1.3.1 REGN LDO

The REGN LDO supplies internal bias circuits as well as the HSFET and LSFET gate drive. The LDO also provides bias rail to TS external resistors. The pull-up rail of STAT and $\overline{\text{PG}}$ (bq24296M) can be connected to REGN as well.

The REGN is enabled when all the conditions are valid.

1. VBUS above $V_{\text{VBUS_UVLOZ}}$
2. VBUS above $V_{\text{BAT}} + V_{\text{SLEEPZ}}$ in buck mode or VBUS below $V_{\text{BAT}} + V_{\text{SLEEP}}$ in boost mode
3. After typical 220ms delay (100ms minimum) is complete

If one of the above conditions is not valid, the device is in high impedance mode (HIZ) with REGN LDO off. The device draws less than I_{VBUS} (15 μA typical) from VBUS during HIZ state. The battery powers up the system when the device is in HIZ.

10.1.3.2 Input Source Qualification

After REGN LDO powers up, the device checks the current capability of the input source. The input source has to meet the following requirements to start the buck converter.

1. VBUS voltage below V_{ACOV} (not in VBUS over-voltage)
2. VBUS voltage above V_{BADSRC} (3.8V typical) when pulling I_{BADSRC} (30mA typical) (poor source detection)

Once the input source passes all the conditions above, the status register REG08[2] goes high and the $\overline{\text{PG}}$ pin (bq24296M) goes low. An INT is asserted to the host.

If the device fails the poor source detection, it will repeat the detection every 2 seconds.

10.1.3.3 Input Current Limit Detection

After the $\overline{\text{PG}}$ is LOW (bq24296M) or REG08[2] goes HIGH, the charger device always runs input current limit detection when a DC source plugs in unless the charger is in HIZ during host mode.

The bq24296M sets input current limit through PSEL and OTG pins. After the input current limit detection is done, the detection result is reported in VBUS_STAT registers (REG08[7:6]) and input current limit is updated in IINLIM register (REG00[2:0]). In addition, host can write to REG00[2:0] to change the input current limit.

10.1.3.4 PSEL/OTG Pins Set Input Current Limit

The bq24296M has PSEL pin which directly takes the USB PHY device output to decide whether the input is USB host or charging port.

Table 2. bq24296M Input Current Limit Detection

PSEL	OTG	INPUT CURRENT LIMIT	REG08[7:6]
HIGH	LOW	100 mA	01
HIGH	HIGH	500 mA	01
LOW	—	3A	10

10.1.3.5 HIZ State wth 100mA USB Host

In battery charging spec, the good battery threshold is the minimum charge level of a battery to power up the portable device successfully. When the input source is 100mA USB host, and the battery is above bat-good threshold (V_{BATGD}), the device follows battery charging spec and enters high impedance state (HIZ). In HIZ state, the device is in the lowest quiescent state with REGN LDO and the bias circuits off. The charger device sets REG00[7] to 1, and the VBUS current during HIZ state will be less than 30 μA . The system is supplied by the battery.

Once the charger device enters HIZ state in host mode, it stays in HIZ until the host writes REG00[7]=0. When the processor host wakes up, it is recommended to first check if the charger is in HIZ state.

In default mode, the charger IC will reset REG00[7] back to 0 when input source is removed. When another source plugs in, the charger IC will run detection again, and update the input current limit.

10.1.3.6 Force Input Current Limit Detection

While adapter is plugged-in, the host can force the charger device to run input current limit detection by setting REG07[7]=1 or when watchdog timeout. During the forced detection, the input current limit is set to 100mA. After the detection is completed, REG07[7] will return to 0 by itself and new input current limit is set based on PSEL/OTG (bq24296M).

10.1.4 Converter Power-Up

After the input current limit is set, the converter is enabled and the HSFET and LSFET start switching. If battery charging is disabled, BATFET turns off. Otherwise, BATFET stays on to charge the battery.

The device provides soft-start when ramp up the system rail. When the system rail is below 2.2V, the input current limit is forced to 100mA. After the system rises above 2.2V, the charger device sets the input current limit set by the lower value between register and ILIM pin.

As a battery charger, the charger deploys a 1.5MHz step-down switching regulator. The fixed frequency oscillator keeps tight control of the switching frequency under all conditions of input voltage, battery voltage, charge current and temperature, simplifying output filter design.

A type III compensation network allows using ceramic capacitors at the output of the converter. An internal saw-tooth ramp is compared to the internal error control signal to vary the duty cycle of the converter. The ramp height is proportional to the PMID voltage to cancel out any loop gain variation due to a change in input voltage.

In order to improve light-load efficiency, the device switches to PFM control at light load when battery is below minimum system voltage setting or charging is disabled. During the PFM operation, the switching duty cycle is set by the ratio of SYS and VBUS.

10.1.5 Boost Mode Operation from Battery

The device supports boost converter operation to deliver power from the battery to other portable devices through USB port. The boost mode output current rating meets the USB On-The-Go 1A output requirement. The maximum output current is 1.5A. The boost operation can be enabled if the following conditions are valid:

1. BAT above BATLOWV threshold (V_{BATLOWV} set by REG04[1])
2. VBUS less than $V_{\text{BAT}} + V_{\text{SLEEP}}$ (in sleep mode)
3. Boost mode operation is enabled (OTG pin HIGH and REG01[5:4]=10)
4. Thermistor Temperature is within boost mode temperature monitor threshold unless BHOT[1:0] is set to 11 (REG06[1:0]) to disable this monitor function
5. After 30ms delay from boost mode enable

In boost mode, the device employs a 1.5MHz step-up switching regulator. Similar to buck operation, the device switches from PWM operation to PFM operation at light load to improve efficiency.

During boost mode, the status register REG08[7:6] is set to 11, the VBUS output is 5V and the output current can reach up to 1A or 1.5A, selected via I²C (REG01[0]). In addition, the device provides adjustable boost voltage from 4.55V to 5.5V by changing BOOSTV bits in REG06[7:4]

Any fault during boost operation, including VBUS over-voltage or over-current, sets the fault register REG09[6] to 1 and an INT is asserted.

10.2 Power Path Management

The device accommodates a wide range of input sources from USB, wall adapter, to car battery. The device provides automatic power path selection to supply the system (SYS) from input source (VBUS), battery (BAT), or both.

Power Path Management (continued)

10.2.1 Narrow VDC Architecture

The device deploys Narrow VDC architecture (NVDC) with BATFET separating system from battery. The minimum system voltage is set by REG01[3:1]. Even with a fully depleted battery, the system is regulated above the minimum system voltage (default 3.5V).

When the battery is below minimum system voltage setting, the BATFET operates in linear mode (LDO mode), and the system is 150mV above the minimum system voltage setting. As the battery voltage rises above the minimum system voltage, BATFET is fully on and the voltage difference between the system and battery is the V_{DS} of BATFET.

When the battery charging is disabled or terminated, the system is always regulated at 150mV above the minimum system voltage setting or battery voltage whichever is higher. The status register REG08[0] goes high when the system is in minimum system voltage regulation.

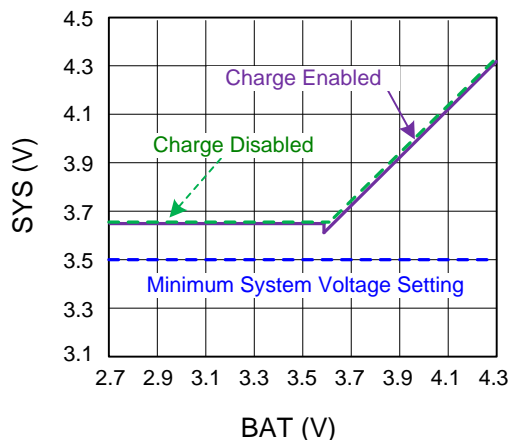


Figure 22. V(SYS) vs V(BAT)

10.2.2 Dynamic Power Management

To meet maximum current limit in USB spec and avoid over loading the adapter, the device features Dynamic Power Management (DPM), which continuously monitors the input current and input voltage.

When input source is over-loaded, either the current exceeds the input current limit (REG00[2:0]) or the voltage falls below the input voltage limit (REG00[6:3]). The device then reduces the charge current until the input current falls below the input current limit and the input voltage rises above the input voltage limit.

When the charge current is reduced to zero, but the input source is still overloaded, the system voltage starts to drop. Once the system voltage falls below the battery voltage, the device automatically enters the supplement mode where the BATFET turns on and battery starts discharging so that the system is supported from both the input source and battery.

During DPM mode (either VINDPM or IINDPM), the status register REG08[3] will go high.

Figure 23 shows the DPM response with 5V/1.2A adapter, 3.2V battery, 2.0A charge current and 3.4V minimum system voltage setting.

Power Path Management (continued)

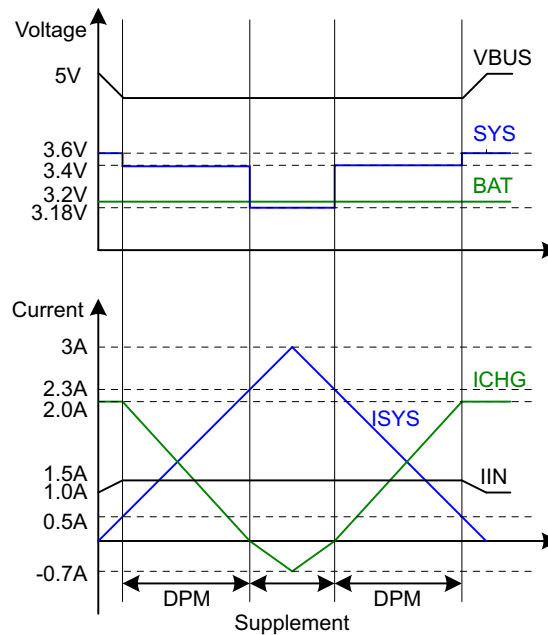


Figure 23. DPM Response

10.2.3 Supplement Mode

When the system voltage falls below the battery voltage, the BATFET turns on and the BATFET gate is regulated so that the minimum BATFET V_{DS} stays at 30mV when the current is low. This prevents oscillation from entering and exiting the supplement mode. As the discharge current increases, the BATFET gate is regulated with a higher voltage to reduce $R_{DS(ON)}$ until the BATFET is in full conduction. At this point onwards, the BATFET V_{DS} linearly increases with discharge current. Figure 24 shows the V-I curve of the BATFET gate regulation operation. BATFET turns off to exit supplement mode when the battery is below battery depletion threshold.

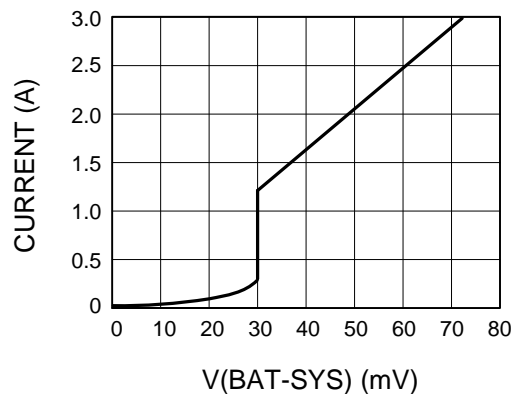


Figure 24. BATFET V-I Curve

10.3 Battery Charging Management

The device charges 1-cell Li-Ion battery with up to 3A charge current for high capacity tablet battery. The 24mΩ BATFET improves charging efficiency and minimizes the voltage drop during discharging.

Battery Charging Management (continued)

10.3.1 Autonomous Charging Cycle

With battery charging enabled at POR (REG01[5:4]=01), the charger device complete a charging cycle without host involvement. The device default charging parameters are listed in the following table.

Table 3. Charging Parameter Default Setting

DEFAULT MODE	bq24296M
Charging Voltage	4.208 V
Charging Current	2.048A
Pre-charge Current	128 mA
Termination Current	256 mA
Temperature Profile	Hot/Cold
Safety Timer	12 hours ⁽¹⁾

(1) See section [Charging Safety Timer](#) for more information.

A new charge cycle starts when the following conditions are valid:

- Converter starts
- Battery charging is enabled by $\dot{f}C$ register bit (REG01[5:4]) = 01 and \overline{CE} is low
- No thermistor fault on TS
- No safety timer fault
- BATFET is not forced to turn off (REG07[5])

The charger device automatically terminates the charging cycle when the charging current is below termination threshold and charge voltage is above recharge threshold. When a full battery voltage is discharged below recharge threshold (REG04[0]), the device automatically starts another charging cycle. After the charge done, either toggle /CE pin or REG01[5:4] will initiate a new charging cycle.

The STAT output indicates the charging status of charging (LOW), charging complete or charge disable (HIGH) or charging fault (Blinking). The status register REG08[5:4] indicates the different charging phases: 00-charging disable, 01-precharge, 10-fast charge (constant current) and constant voltage mode, 11-charging done. Once a charging cycle is complete, an INT is asserted to notify the host.

The host can always control the charging operation and optimize the charging parameters by writing to the registers through I²C.

10.3.2 Battery Charging Profile

The device charges the battery in three phases: preconditioning, constant current and constant voltage. At the beginning of a charging cycle, the device checks the battery voltage and applies current.

Table 4. Charging Current Setting

VBAT	CHARGING CURRENT	REG DEFAULT SETTING	REG08[5:4]
$V_{BAT} < V_{SHORT}$ (Typical 2V)	100mA	–	01
$V_{SHORT} \leq V_{BAT} < V_{BATLOWV}$ (Typical $2V \leq V_{BAT} < 3V$)	REG03[7:4]	128mA	01
$V_{BAT} \geq V_{BATLOWV}$ (Typical $V_{BAT} \geq 3V$)	REG02[7:2]	2048mA	10

If the charger device is in DPM regulation or thermal regulation during charging, the actual charging current will be less than the programmed value. In this case, termination is temporarily disabled and the charging safety timer is counted at half the clock rate.

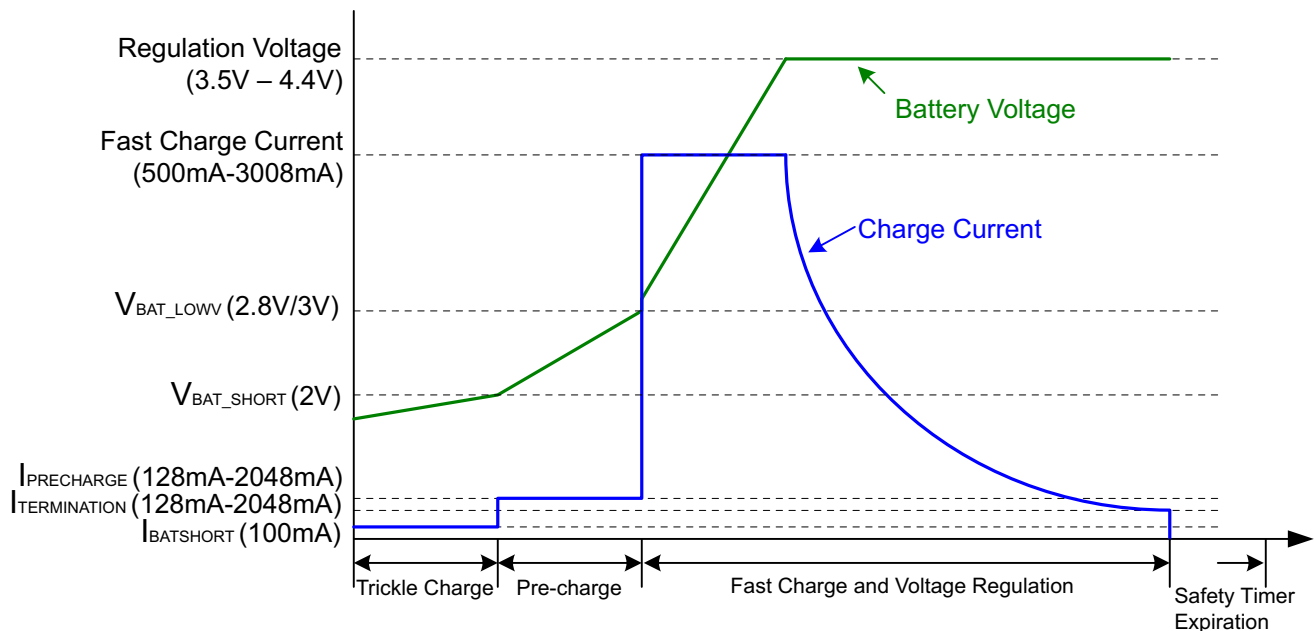


Figure 25. Battery Charging Profile

10.3.3 Thermistor Qualification

The charger device provides a single thermistor input for battery temperature monitor.

10.3.3.1 Cold/Hot Temperature Window

The device continuously monitors battery temperature by measuring the voltage between the TS pin and ground, typically determined by a negative temperature coefficient thermistor and an external voltage divider. The device compares this voltage against its internal thresholds to determine if charge or boost is allowed.

To initiate a charge cycle, the battery temperature must be within the V_{LTF} to V_{HTF} thresholds. During the charge cycle the battery temperature must be within the V_{LTF} to V_{TCO} thresholds, else the device suspends charging and waits until the battery temperature is within the V_{LTF} to V_{HTF} range.

For battery protection during boost mode, the device monitors the battery temperature to be within the $VBCOLDx$ to $VBHOTx$ thresholds unless boost mode temperature is disabled by setting BHOT bits (REG06[3:2]) to 11. When temperature is outside of the temperature thresholds, the boost mode is suspended and REG08[7:6] bits (VBUS_STAT) are set to 00. Once temperature returns within thresholds, the boost mode is recovered.

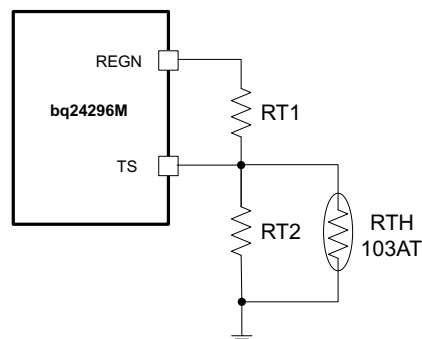


Figure 26. TS Resistor Network

When the TS fault occurs, the fault register REG09[2:0] indicates the actual condition on each TS pin and an INT is asserted to the host. The STAT pin indicates the fault when charging is suspended.

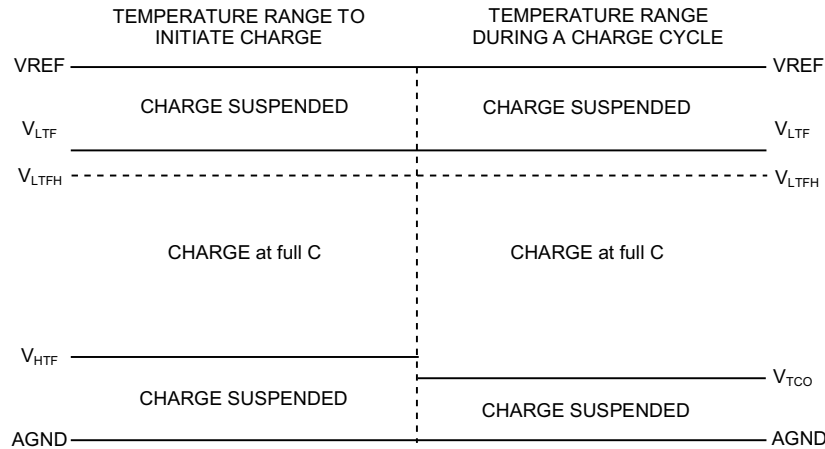


Figure 27. TS Pin Thermistor Sense Thresholds in Charge Mode

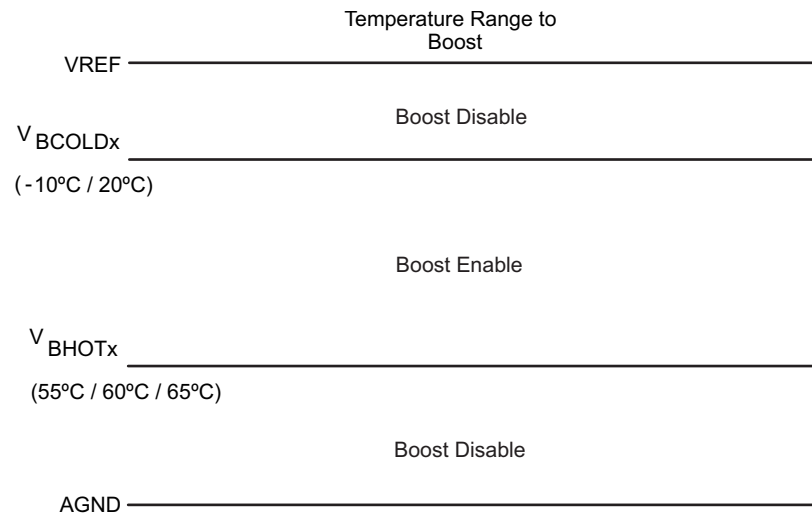


Figure 28. TS Pin thermistor Sense Thresholds in Boost Mode

Assuming a 103AT NTC thermistor is used on the battery pack [Figure 27](#), the value RT1 and RT2 can be determined by using the following equation:

$$RT2 = \frac{V_{VREF} \times RTH_{COLD} \times RTH_{HOT} \times \left(\frac{1}{V_{LTF}} - \frac{1}{V_{TCO}} \right)}{RTH_{HOT} \times \left(\frac{V_{VREF}}{V_{TCO}} - 1 \right) - RTH_{COLD} \times \left(\frac{V_{VREF}}{V_{LTF}} - 1 \right)}$$

$$RT1 = \frac{\frac{V_{VREF}}{V_{LTF}} - 1}{\frac{1}{RT2} + \frac{1}{RTH_{COLD}}}$$

(1)

Select 0°C to 45°C range for Li-ion or Li-polymer battery,
 $RTH_{COLD} = 27.28 \text{ k}\Omega$
 $RTH_{HOT} = 4.911 \text{ k}\Omega$

RT1 = 5.25 kΩ
RT2 = 31.23 kΩ

10.3.4 Charging Termination

The device terminates a charge cycle when the battery voltage is above recharge threshold, and the current is below termination current. After the charging cycle is complete, the BATFET turns off. The converter keeps running to power the system, and BATFET can turn back on to engage supplement mode.

When termination occurs, the status register REG08[5:4] is 11, and an INT is asserted to the host. Termination is temporarily disabled if the charger device is in input current/voltage regulation or thermal regulation. Termination can be disabled by writing 0 to REG05[7].

10.3.4.1 Termination when REG02[0] = 1

When REG02[0] is HIGH to reduce the charging current by 80%, the charging current could be less than the termination current. The charger device termination function should be disabled. When the battery is charged to fully capacity, the host disables charging through \overline{CE} pin or REG01[5:4].

10.3.5 Charging Safety Timer

The device has safety timer to prevent extended charging cycle due to abnormal battery conditions. The safety timer is 4 hours when the battery is below batlowv threshold. The user can program fast charge safety timer (default 12 hours) through I2C (REG05[2:1]). When safety timer expires, the fault register REG09[5:4] goes 11 and an INT is asserted to the host. The safety timer feature can be disabled via I2C (REG05[3]).

The following actions restart the safety timer after safety timer expires:

- Toggle the \overline{CE} pin HIGH to LOW to HIGH (charge enable)
- Write REG01[5:4] from 00 to 01 (charge enable)
- Write REG05[3] from 0 to 1 (safety timer enable)

During input voltage/current regulation, thermal regulation, or FORCE_20PCT bit (REG02[0]) is set, the safety timer counting at half clock rate since the actual charge current is likely to be below the register setting. For example, if the charger is in input current regulation (IINDPM) throughout the whole charging cycle, and the safety time is set to 5 hours, the safety timer will expire in 10 hours. This feature can be disabled by writing 0 to REG07[6].

10.3.5.1 Safety Timer Configuration Change

When safety timer value needs to be changed, it is recommended that the timer is disabled first before new configuration is written to REG05[2:1]. The safety timer can be disabled by writing 1 to REG05[3]. This ensures the safety timer restart counting after new value is configured.

10.3.6 USB Timer when Charging from USB100mA Source

The total charging time in default mode from USB100mA source is limited by a 45-min max timer. At the end of the timer, the device stops the converter and goes to HIZ.

10.4 Host Mode and Default Mode

The device is a host controlled device, but it can operate in default mode without host management. In default mode, the device can be used as an autonomous charger with no host or with host in sleep.

When the charger is in default mode, REG09[7] is HIGH. When the charger is in host mode, REG09[7] is LOW. After power-on-reset, the device starts in watchdog timer expiration state, or default mode. All the registers are in the default settings. The device keeps charging the battery by default with 12-hour fast charging safety timer. At the end of the 12 hours, the charging is stopped and the buck converter continues to operate to supply system load.

Any write command to device transitions the device from default mode to host mode. All the device parameters can be programmed by the host. To keep the device in host mode, the host has to reset the watchdog timer by writing 1 to REG01[6] before the watchdog timer expires (REG05[5:4]), or disable watchdog timer by setting REG05[5:4]=00.

Host Mode and Default Mode (continued)

When the host changes watchdog timer configuration (REG05[5:4]), it is recommended to first disable watchdog by writing 00 to REG05[5:4] and then change the watchdog to new timer values. This ensures the watchdog timer is restarted after new value is written.

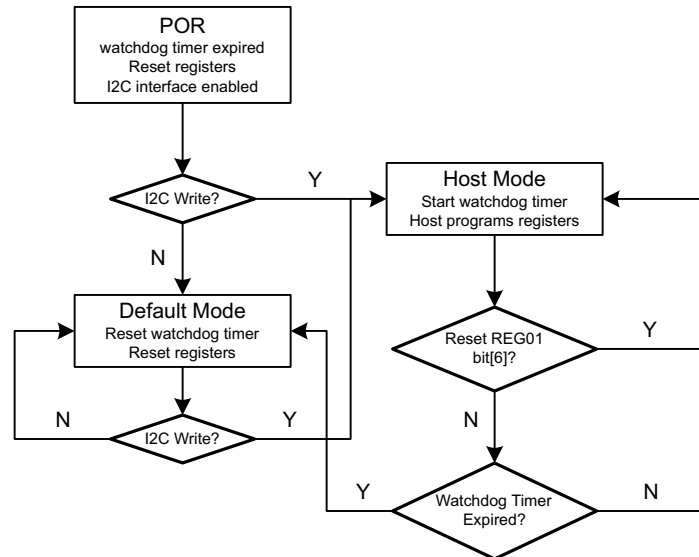


Figure 29. Watchdog Timer Flow Chart

10.4.1 Plug in USB100mA Source with Good Battery

When the input source is detected as 100mA USB host, and the battery voltage is above batgood threshold (V_{BATGD}), the charger device enters HIZ state to meet the battery charging spec requirement.

If the charger device is in host mode, it will stay in HIZ state even after the USB100mA source is removed, and the adapter plugs in. During the HIZ state, REG00[7] is set HIGH and the system load is supplied from battery. It is recommended that the processor host always checks if the charger IC is in HIZ state when it wakes up. The host can write REG00[7] to 0 to exit HIZ state.

If the charger is in default mode, when the DC source is removed, the charger device will get out of HIZ state automatically. When the input source plugs in again, the charger IC runs detection on the input source and update the input current limit.

10.4.2 USB Timer when Charging from USB100mA Source

The total charging time in default mode from USB100mA source is limited by a 45-min max timer. At the end of the timer, the device stops the converter and goes to HIZ.

10.5 Status Outputs (\overline{PG} , STAT, and INT)

10.5.1 Power Good Indicator (\overline{PG}) (bq24296M)

In bq24296M, \overline{PG} goes LOW to indicate a good input source when:

1. VBUS above V_{BUS_UVLO}
2. VBUS above battery (not in sleep)
3. VBUS below V_{ACOV} threshold
4. VBUS above V_{BUS_MIN} when I_{BADSRC} current is applied (not a poor source)

10.5.2 Charging Status Indicator (STAT)

The device indicates charging state on the open drain STAT pin. The STAT pin can drive LED as the application diagram shows.

Table 5. STAT Pin State

CHARGING STATE	STAT
Charging in progress (including recharge)	LOW
Charging complete	HIGH
Sleep mode, charge disable	HIGH

10.5.3 Interrupt to Host (INT)

In some applications, the host does not always monitor the charger operation. The INT notifies the system on the device operation. The following events will generate 256us INT pulse.

1. USB/adaptor source identified (through PSEL detection and OTG pin)
2. Good input source detected
 - not in sleep
 - VBUS below V_{ACOV} threshold
 - current limit above I_{BADSRC}
3. Input removed or VBUS above V_{ACOV} threshold
4. Charge Complete
5. Any FAULT event in REG09

For the first four events, INT pulse is always generated. For the last event, when a fault occurs, the charger device sends out INT and latches the fault state in REG09 until the host reads the fault register. If a prior fault exists, the charger device would not send any INT upon new faults except NTC fault (REG09[2:0]). The NTC fault is not latched and always reports the current thermistor conditions. In order to read the current fault status, the host has to read REG09 two times consecutively. In order to read the current fault status, the host has to read REG09 two times consecutively. The 1st reads fault register status from the last read and the 2nd reads the current fault register status.

10.6 Protections

10.6.1 Input Current Limit on ILIM

For safe operation, the device has an additional hardware pin on ILIM to limit maximum input current on ILIM pin. The input maximum current is set by a resistor from ILIM pin to ground as:

$$I_{INMAX} = \frac{1V}{R_{ILIM}} \times K_{LIM} \quad (2)$$

The actual input current limit is the lower value between ILIM setting and register setting (REG00[2:0]). For example, if the register setting is 111 for , and ILIM has a 316Ω resistor to ground for 1.5A, the input current limit is 1.5A. ILIM pin can be used to set the input current limit rather than the register settings.

The device regulates ILIM pin at 1V. If ILIM voltage exceeds 1V, the device enters input current regulation (Refer to *Dynamic Power Path Management* section).

The voltage on ILIM pin is proportional to the input current. ILIM pin can be used to monitor the input current following [Equation 3](#):

$$I_{IN} = \frac{V_{ILIM}}{1V} \times I_{INMAX} \quad (3)$$

For example, if ILIM pin sets 2A, and the ILIM voltage is 0.75V, the actual input current 1.5A. If ILIM pin is open, the input current is limited to zero since ILIM voltage floats above 1V. If ILIM pin is short, the input current limit is set by the register.

10.6.2 Thermal Regulation and Thermal Shutdown

During charge operation, the device monitors the internal junction temperature T_j to avoid overheat the chip and limits the IC surface temperature. When the internal junction temperature exceeds the preset limit (REG06[1:0]), the device lowers down the charge current. The wide thermal regulation range from 60°C to 120°C allows the user to optimize the system thermal performance.

Protections (continued)

During thermal regulation, the actual charging current is usually below the programmed battery charging current. Therefore, termination is disabled, the safety timer runs at half the clock rate, and the status register REG08[1] goes high.

Additionally, the device has thermal shutdown to turn off the converter. The fault register REG09[5:4] is 10 and an INT is asserted to the host.

10.6.3 Voltage and Current Monitoring in Buck Mode

The device closely monitors the input and system voltage, as well as HSFET and LSFET current for safe buck mode operation.

10.6.3.1 Input Over-Voltage (ACOV)

The maximum input voltage for buck mode operation is V_{VBUS_OP} . If VBUS voltage exceeds V_{ACOV} , the device stops switching immediately. During input over voltage (ACOV), the fault register REG09[5:4] will be set to 01. An INT is asserted to the host.

10.6.3.2 System Over-Voltage Protection (SYSOVP)

The charger device clamps the system voltage during load transient so that the components connect to system would not be damaged due to high voltage. When SYSOVP is detected, the converter stops immediately to clamp the overshoot.

10.6.4 Voltage and Current Monitoring in Boost Mode

The charger device closely monitors the VBUS voltage, as well as HSFET and LSFET current to ensure safe boost mode operation.

10.6.4.1 Over-Current Protection

The charger device closely monitors the RBFET (Q1), HSFET (Q2), and LSFET (Q3) current to ensure safe boost mode operation. During over-current condition, the device will operate in hiccup mode for protection. While in hiccup mode cycle, the device turns off RBFET for $t_{OTG_OCP_OFF}$ (32ms typical) and turns on RBFET for $t_{OTG_OCP_ON}$ (260us typical) in an attempt to restart. If the over-current condition is removed, the boost converter will maintain the RBFET on state and the VBUS OTG output will operate normally. When over-current condition continues to exist, the device will repeat the hiccup cycle until over-current condition is removed. When over-current condition is detected, the fault register bit BOOST_FAULT (REG09[6]) is set high to indicate fault in boost operation. An INT is asserted to the host.

10.6.4.2 VBUS Over-Voltage Protection

When an adapter plugs in during boost mode, the VBUS voltage will rise above regulation target. Once the VBUS voltage exceeds V_{OTG_OVP} , the device stops switching and the device exits boost mode. During the over-voltage, the fault register bit BOOST_FAULT (REG09[6]) is set high to indicate fault in boost operation. An INT is asserted to the host.

10.6.5 Battery Protection

10.6.5.1 Battery Over-Voltage Protection (BATOVP)

The battery over-voltage limit is clamped at V_{BAT_OVP} (4% nominal) above the battery regulation voltage. When battery over voltage occurs, the charger device immediately disables charge. The fault register REG09[5] goes high and an INT is asserted to the host.

10.6.5.2 Battery Short Protection

If the battery voltage falls below V_{short} (2V typical), the device immediately turns off BATFET to disable the battery charging or supplement mode. 1ms later, the BATFET turns on and charge the battery with 100mA current. The device does not turn on BATFET to discharge a battery that is below 2.5V.

10.7 Serial Interface

The device uses I²C compatible interface for flexible charging parameter programming and instantaneous device status reporting. I²C™ is a bi-directional 2-wire serial interface developed by Philips Semiconductor (now NXP Semiconductors). Only two bus lines are required: a serial data line (SDA) and a serial clock line (SCL). Devices can be considered as masters or slaves when performing data transfers. A master is the device which initiates a data transfer on the bus and generates the clock signals to permit that transfer. At that time, any device addressed is considered a slave.

The device operates as a slave device with address 6BH, receiving control inputs from the master device like micro controller or a digital signal processor. The I²C interface supports both standard mode (up to 100kbits), and fast mode (up to 400kbits).

Both SDA and SCL are bi-directional lines, connecting to the positive supply voltage via a current source or pull-up resistor. When the bus is free, both lines are HIGH. The SDA and SCL pins are open drain.

10.7.1 Data Validity

The data on the SDA line must be stable during the HIGH period of the clock. The HIGH or LOW state of the data line can only change when the clock signal on the SCL line is LOW. One clock pulse is generated for each data bit transferred.

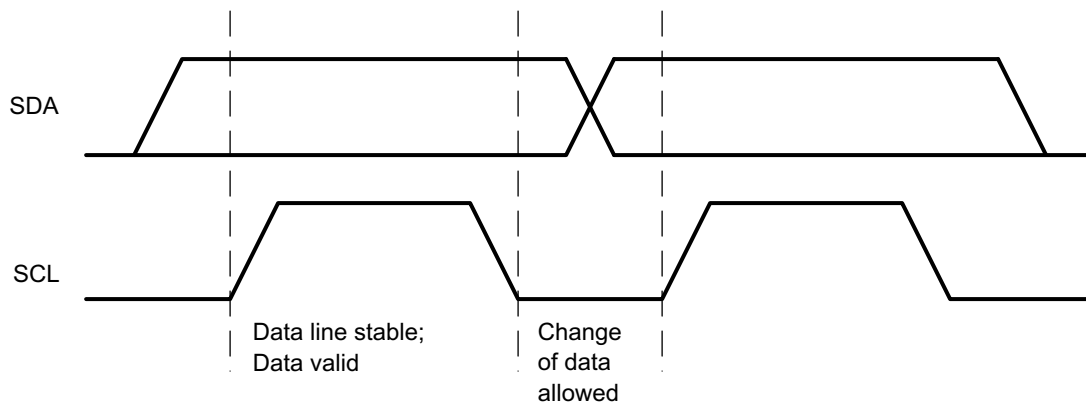


Figure 30. Bit Transfer on the I²C Bus

10.7.2 START and STOP Conditions

All transactions begin with a START (S) and can be terminated by a STOP (P). A HIGH to LOW transition on the SDA line while SCL is HIGH defines a START condition. A LOW to HIGH transition on the SDA line when the SCL is HIGH defines a STOP condition.

START and STOP conditions are always generated by the master. The bus is considered busy after the START condition, and free after the STOP condition.

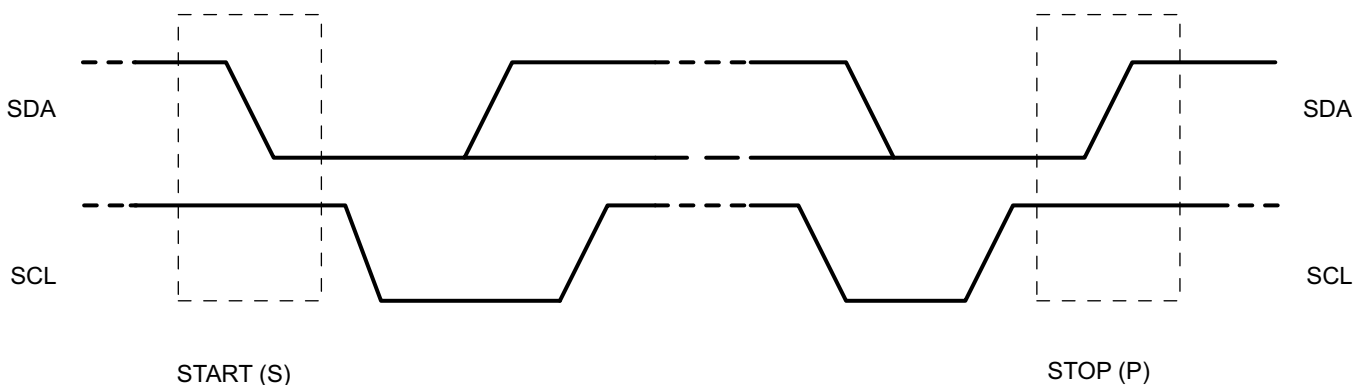


Figure 31. START and STOP conditions

Serial Interface (continued)

10.7.3 Byte Format

Every byte on the SDA line must be 8 bits long. The number of bytes to be transmitted per transfer is unrestricted. Each byte has to be followed by an Acknowledge bit. Data is transferred with the Most Significant Bit (MSB) first. If a slave cannot receive or transmit another complete byte of data until it has performed some other function, it can hold the clock line SCL low to force the master into a wait state (clock stretching). Data transfer then continues when the slave is ready for another byte of data and release the clock line SCL.

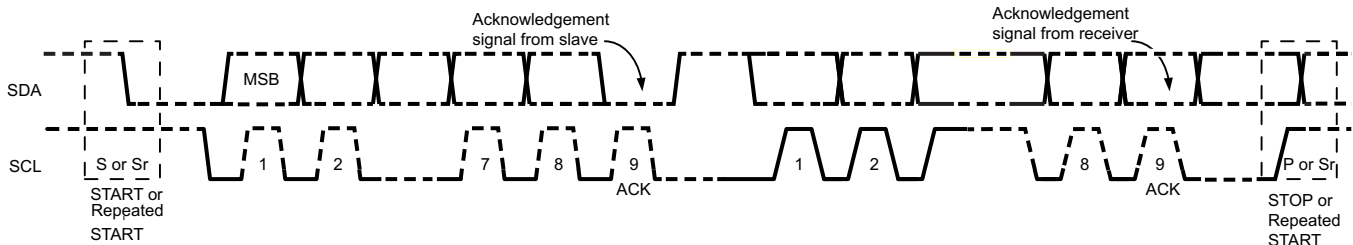


Figure 32. Data Transfer on the I²C Bus

10.7.4 Acknowledge (ACK) and Not Acknowledge (NACK)

The acknowledge takes place after every byte. The acknowledge bit allows the receiver to signal the transmitter that the byte was successfully received and another byte may be sent. All clock pulses, including the acknowledge 9th clock pulse, are generated by the master.

The transmitter releases the SDA line during the acknowledge clock pulse so the receiver can pull the SDA line LOW and it remains stable LOW during the HIGH period of this clock pulse.

When SDA remains HIGH during the 9th clock pulse, this is the Not Acknowledge signal. The master can then generate either a STOP to abort the transfer or a repeated START to start a new transfer.

10.7.5 Slave Address and Data Direction Bit

After the START, a slave address is sent. This address is 7 bits long followed by the eighth bit as a data direction bit (bit R/W). A zero indicates a transmission (WRITE) and a one indicates a request for data (READ).

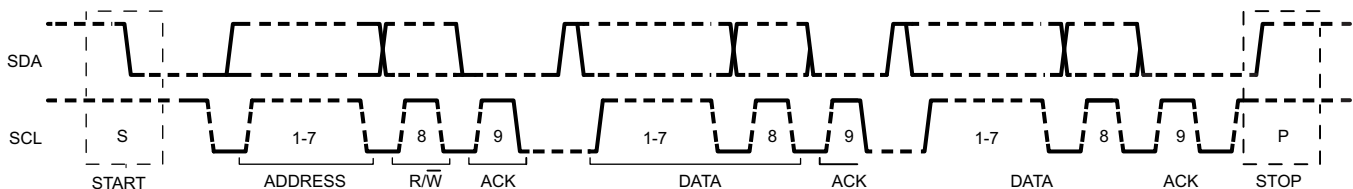


Figure 33. Complete Data Transfer

10.7.5.1 Single Read and Write

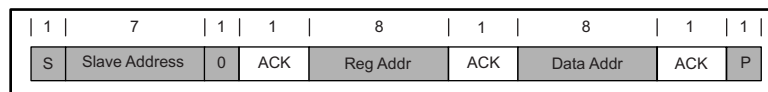


Figure 34. Single Write

Serial Interface (continued)

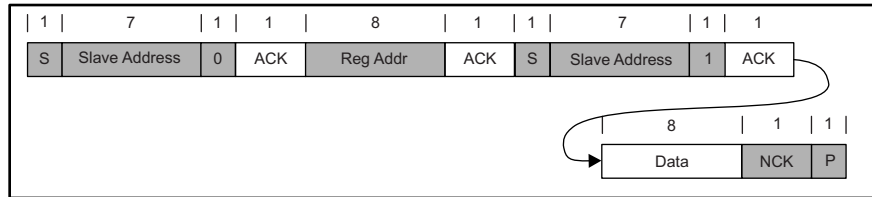


Figure 35. Single Read

If the register address is not defined, the charger IC send back NACK and go back to the idle state.

10.7.5.2 Multi-Read and Multi-Write

The charger device supports multi-read and multi-write on REG00 through REG08.

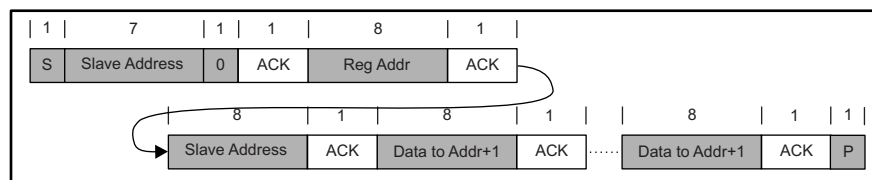


Figure 36. Multi-Write

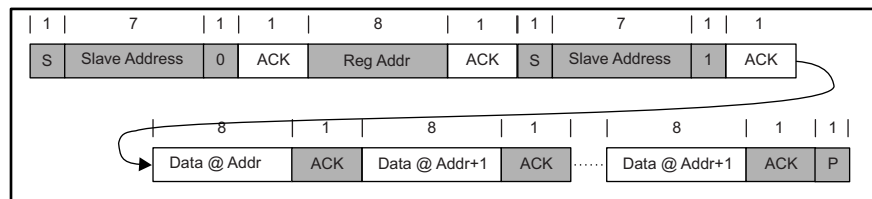


Figure 37. Multi-Read

The fault register REG09 locks the previous fault and only clears it after the register is read. For example, if Charge Safety Timer Expiration fault occurs but recovers later, the fault register REG09 reports the fault when it is read the first time, but returns to normal when it is read the second time. To verify real time fault, the fault register REG09 should be read twice to get the real condition. In addition, the fault register REG09 does not support multi-read or multi-write.

REG09 is a fault register. It keeps all the fault information from last read until the host issues a new read. For example, if there is a TS fault but gets recovered immediately, the host still sees TS fault during the first read. In order to get the fault information at present, the host has to read REG09 for the second time. REG09 doesn't support multi-read and multi-write.

11 Application Information

11.1 Inductor Selection

The device has 1.5 MHz switching frequency to allow the use of small inductor and capacitor values. The inductor saturation current should be higher than the charging current (I_{CHG}) plus half the ripple current (I_{RIPPLE}):

$$I_{SAT} \geq I_{CHG} + (1/2) I_{RIPPLE} \quad (4)$$

The inductor ripple current depends on input voltage (V_{BUS}), duty cycle ($D = V_{BAT}/V_{BUS}$), switching frequency (f_s) and inductance (L):

$$I_{RIPPLE} = \frac{V_{IN} \times D \times (1-D)}{f_s \times L} \quad (5)$$

The maximum inductor ripple current happens with $D = 0.5$ or close to 0.5. Usually inductor ripple is designed in the range of (20–40%) maximum charging current as a trade-off between inductor size and efficiency for a practical design.

11.2 Input Capacitor

Input capacitor should have enough ripple current rating to absorb input switching ripple current. The worst case RMS ripple current is half of the charging current when duty cycle is 0.5. If the converter does not operate at 50% duty cycle, then the worst case capacitor RMS current I_{CIN} occurs where the duty cycle is closest to 50% and can be estimated by the following equation:

$$I_{CIN} = I_{CHG} \times \sqrt{D \times (1-D)} \quad (6)$$

For best performance, V_{BUS} should be decouple to PGND with 1 μ F capacitance. The remaining input capacitor should be placed on PMID.

Low ESR ceramic capacitor such as X7R or X5R is preferred for input decoupling capacitor and should be placed to the drain of the high side MOSFET and source of the low side MOSFET as close as possible. Voltage rating of the capacitor must be higher than normal input voltage level. 25V rating or higher capacitor is preferred for 15V input voltage. 22 μ F capacitance is suggested for typical of 3-4A charging current.

11.3 Output Capacitor

Output capacitor also should have enough ripple current rating to absorb output switching ripple current. The output capacitor RMS current I_{COUT} is given:

$$I_{COUT} = \frac{I_{RIPPLE}}{2 \times \sqrt{3}} \approx 0.29 \times I_{RIPPLE} \quad (7)$$

The output capacitor voltage ripple can be calculated as follows:

$$\Delta V_O = \frac{V_{OUT}}{8LCf_s^2} \left(1 - \frac{V_{OUT}}{V_{IN}} \right) \quad (8)$$

At certain input/output voltage and switching frequency, the voltage ripple can be reduced by increasing the output filter LC.

The charger device has internal loop compensator. To get good loop stability, the resonant frequency of the output inductor and output capacitor should be designed between 15kHz and 25kHz. The preferred ceramic capacitor is 6V or higher rating, X7R or X5R.

11.4 PCB Layout

The switching node rise and fall times should be minimized for minimum switching loss. Proper layout of the components to minimize high frequency current path loop (see [Figure 38](#)) is important to prevent electrical and magnetic field radiation and high frequency resonant problems. Here is a PCB layout priority list for proper layout. Layout PCB according to this specific order is essential.

1. Place input capacitor as close as possible to PMID pin and GND pin connections and use shortest copper trace connection or GND plane.
2. Place inductor input terminal to SW pin as close as possible. Minimize the copper area of this trace to lower electrical and magnetic field radiation but make the trace wide enough to carry the charging current. Do not use multiple layers in parallel for this connection. Minimize parasitic capacitance from this area to any other trace or plane.
3. Put output capacitor near to the inductor and the IC. Ground connections need to be tied to the IC ground with a short copper trace connection or GND plane.
4. Route analog ground separately from power ground. Connect analog ground and connect power ground separately. Connect analog ground and power ground together using power pad as the single ground connection point. Or using a 0Ω resistor to tie analog ground to power ground.
5. Use single ground connection to tie charger power ground to charger analog ground. Just beneath the IC. Use ground copper pour but avoid power pins to reduce inductive and capacitive noise coupling.
6. Decoupling capacitors should be placed next to the IC pins and make trace connection as short as possible.
7. It is critical that the exposed power pad on the backside of the IC package be soldered to the PCB ground. Ensure that there are sufficient thermal vias directly under the IC, connecting to the ground plane on the other layers.
8. The via size and number should be enough for a given current path.

See the EVM design for the recommended component placement with trace and via locations. For the QFN information, refer to [SCBA017](#) and [SLUA271](#).

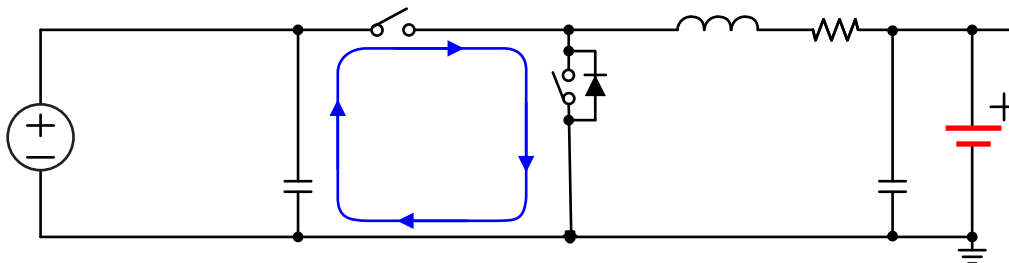


Figure 38. High Frequency Current Path

PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead/Ball Finish (6)	MSL Peak Temp (3)	Op Temp (°C)	Device Marking (4/5)	Samples
BQ24296MRGER	PREVIEW	VQFN	RGE	24		Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	-40 to 85		
BQ24296MRGET	PREVIEW	VQFN	RGE	24		Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	-40 to 85		

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check <http://www.ti.com/productcontent> for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

Pb-Free (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

(3) MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

(4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

(5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "-" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

(6) Lead/Ball Finish - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead/Ball Finish values may wrap to two lines if the finish value exceeds the maximum column width.

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PACKAGE OPTION ADDENDUM

2-Mar-2014

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TAPE AND REEL INFORMATION



QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
BQ24296MRGER	VQFN	RGE	24	0	330.0	12.4	4.25	4.25	1.15	8.0	12.0	Q2
BQ24296MRGET	VQFN	RGE	24	0	180.0	12.4	4.25	4.25	1.15	8.0	12.0	Q2

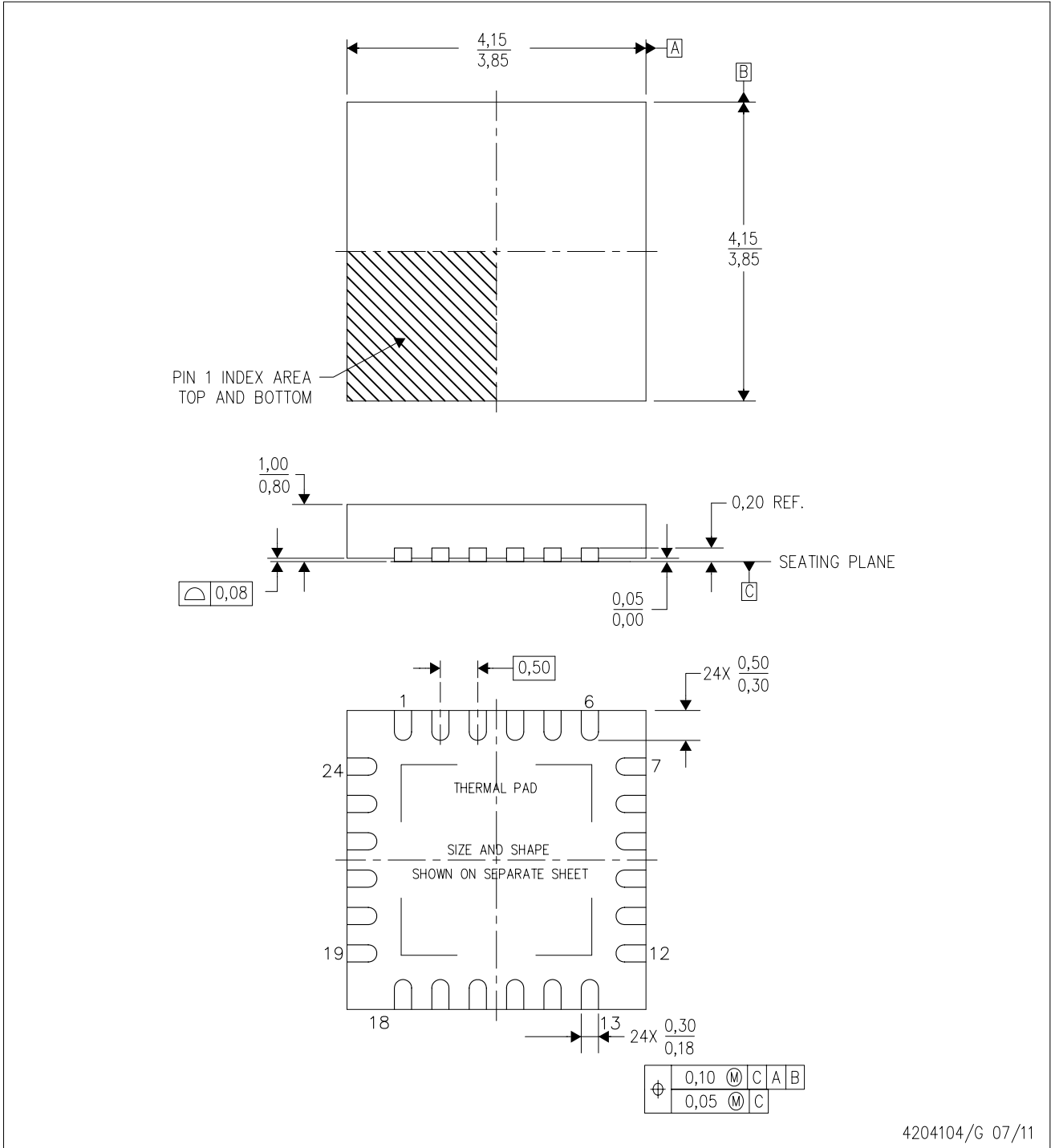
TAPE AND REEL BOX DIMENSIONS


*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
BQ24296MRGER	VQFN	RGE	24	0	367.0	367.0	35.0
BQ24296MRGET	VQFN	RGE	24	0	210.0	185.0	35.0

RGE (S-PVQFN-N24)

PLASTIC QUAD FLATPACK NO-LEAD



4204104/G 07/11

- NOTES:
- A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M-1994.
 - B. This drawing is subject to change without notice.
 - C. Quad Flatpack, No-Leads (QFN) package configuration.
 - D. The package thermal pad must be soldered to the board for thermal and mechanical performance.
 - E. See the additional figure in the Product Data Sheet for details regarding the exposed thermal pad features and dimensions.
 - F. Falls within JEDEC MO-220.

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